



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE1 (4층, 로비)

## [WP] 포스터세션

### E. Compound Semiconductors 분과

WP-075	<p><b>Segmented-PiN 구조를 통한 고효율 4H-SiC UV 포토다이오드 설계</b> 김상엽<sup>1</sup>, 최수빈<sup>2</sup>, 박가영<sup>2</sup>, 백두산<sup>1</sup>, 정승완<sup>1</sup>, 석오균<sup>2</sup> <sup>1</sup>부산대학교 전기전자공학과, <sup>2</sup>부산대학교 전기전자공학부</p>
WP-076	<p><b>빠른 스위칭 동작에서의 SBD 내장형 SiC MOSFET의 스위칭 특성 분석</b> 강규혁<sup>1</sup>, 정승완<sup>1</sup>, 백두산<sup>1</sup>, 박진우<sup>2</sup>, 류종현<sup>3</sup>, 석오균<sup>2</sup> <sup>1</sup>부산대학교 전기전자공학과, <sup>2</sup>부산대학교 전기전자공학부, <sup>3</sup>부산대학교 기계공학부</p>
WP-077	<p><b>이중 식각을 통한 전계 완화형 6.5 kV SiC PiN 다이오드 종단 구조 설계</b> 박수민<sup>1</sup>, 김상엽<sup>1</sup>, 정준기<sup>1</sup>, 양승리<sup>2</sup>, 백두산<sup>1</sup>, 정승완<sup>1</sup>, 석오균<sup>2</sup> <sup>1</sup>부산대학교 전기전자공학과, <sup>2</sup>부산대학교 전기전자공학부</p>
WP-078	<p><b>채널링 이온주입을 적용한 1.2kV 급 SiC MOSFET 단락 보호 특성 향상에 관한 연구</b> 정준기<sup>1</sup>, 박수민<sup>1</sup>, 백두산<sup>1</sup>, 정승완<sup>1</sup>, 양승리<sup>2</sup>, 석오균<sup>2</sup> <sup>1</sup>부산대학교 전기전자공학과, <sup>2</sup>부산대학교 전기전자공학부</p>
WP-079	<p><b>High-Performance AlGaN/GaN-on-Si HEMTs with Controlled Trapping Effects by Periodically Carbon-Doped GaN Buffer and in-Situ SiN Passivation</b> Donghan Kim<sup>1</sup>, Honghwi Park<sup>1,2</sup>, Seung-Hyun Kang<sup>1</sup>, Youngjin Park<sup>1</sup>, Hongsik Park<sup>1</sup>, and Jung-Hee Lee<sup>1,3</sup> <sup>1</sup>School of Electronic and Electrical Engineering, Kyungpook National University, <sup>2</sup>School of Electronic Engineering, Kumoh National Institute of Technology, <sup>3</sup>L&amp;D Co., Ltd.</p>



WP-080	<p><b>Analysis of Temperature Characteristics and Zero Temperature Coefficients for AlGaN/GaN MIS-HEMT Irradiated by Proton</b></p> <p>Soo Bean Song<sup>1</sup>, Jin Park<sup>1</sup>, Won Suk Koh<sup>1</sup>, Gang San Yun<sup>1</sup>, Kyeong Min Lim<sup>1</sup>, Young Jun Yoon<sup>2</sup>, and In Man Kang<sup>1</sup></p> <p><sup>1</sup>School of Electronic and Electrical Engineering, Kyungpook National University, <sup>2</sup>Department of Electronics and Mechanical Engineering, Gyeongkuk National University</p>
WP-081	<p><b>Analysis of Schottky-Like Ohmic Behavior in Al-Rich AlGaN HEMTs</b></p> <p>Sakhone Pharkphoumy and Hyun-Seop Kim</p> <p>Department of Electrical Engineering, Kunsan National University</p>
WP-082	<p><b>Effect of Proton Irradiation on the Electrical Performance of SnO<sub>2</sub> Field-Effect Transistor with ITO Electrodes</b></p> <p>Huisseung Kim<sup>1</sup>, Jeongtae Kim<sup>2</sup>, Seonchang Kim<sup>2</sup>, Suhyeon Park<sup>1</sup>, Dawon Lee<sup>1</sup>, Jiseop Byeon<sup>1</sup>, Jeongin Seo<sup>1</sup>, Dong-Seok Kim<sup>2</sup>, and Roy Byung Kyu Chung<sup>1</sup></p> <p><sup>1</sup>Department of Advanced Materials Science and Engineering, Kyungpook National University, <sup>2</sup>Korea Multi-purpose Accelerator Complex, KAERI</p>
WP-083	<p><b>Impact of AlGaN Channel Thickness on the Mobility and Reliability of Al-Rich AlGaN Channel HEMTs</b></p> <p>Shyam Mohan, Joocheol Jeong, Jaejin Heo, Hyogeun Cho, Mingoo Jo, Minyeong Kim, and Okhyun Nam</p> <p>Convergence Center for Advanced Nano Semiconductor, Department of Semiconductor Engineering, Tech University of Korea</p>
WP-084	<p><b>광 입사 방식에 따른 알파 산화 갈륨 UV-C 광 검출기 성능 비교</b></p> <p>조영관<sup>1</sup>, 김용기<sup>1</sup>, 신명훈<sup>1</sup>, 박지현<sup>2</sup>, 전대우<sup>2</sup></p> <p><sup>1</sup>한국항공대학교 반도체학과 우주시스템융합전공, <sup>2</sup>세라믹기술원 디스플레이소재센터</p>
WP-085	<p><b>InP Double-Heterojunction Bipolar Transistors with Compact Modeling for High-Frequency and THz Application</b></p> <p>Hyeon-Bhin Jo and Ki-Jin Kim</p> <p>ICT Device and Packaging Center, KETI</p>
WP-086	<p><b>La<sub>2</sub>O<sub>3</sub> 중간층을 통한 In<sub>2</sub>O<sub>3</sub> 박막 트랜지스터의 전기적 성능 및 신뢰성 향상</b></p> <p>박동욱<sup>1</sup>, 박영근<sup>1</sup>, 김승훈<sup>1</sup>, 신건희<sup>2</sup>, 정원묵<sup>1</sup>, 유찬미<sup>2</sup>, 이동규<sup>2</sup>, 조병진<sup>1,2</sup></p> <p><sup>1</sup>한국과학기술원 전기 및 전자공학부, <sup>2</sup>한국과학기술원 반도체공학대학원</p>



WP-087	<p><b>Al–Rich AlGaN Channel HEMT Structures with Compositionally Graded AlGaN Contact Layer</b></p> <p>Hyogeun Cho, Joocheol Jeong, Shyam Mohan, Jaejin Heo, Minyeong Kim, Mingoo Jo, and Okhyun Nam</p> <p>Convergence Center for Advanced Nano Semiconductor, Department of Semiconductor Engineering, Tech University of Korea</p>
WP-088	<p><b>In–Situ SiN<sub>x</sub> Interlayer for Ohmic Contacts in Al–Rich AlGaN Channel HEMTs</b></p> <p>Joocheol Jeong, Shyam Mohan, Jaejin Heo, Hyogeun Cho, Mingoo Jo, Minyeong Kim, and Okhyun Nam</p> <p>Convergence Center for Advanced Nano Semiconductor, Department of Nano–Semiconductor, Tech University of Korea</p>
WP-089	<p><b>Ellipsometric Study on the Temperature–Dependent Optical Properties of <math>\beta</math>–InSe</b></p> <p>DooHyeon Lee<sup>1</sup>, Yihyun Moon<sup>1</sup>, DongMin Kim<sup>1</sup>, Tae Jung Kim<sup>1</sup>, Long V. Le<sup>2</sup>, Xuan Au Nguyen<sup>1</sup>, and Junho Choi<sup>1</sup></p> <p><sup>1</sup>Department of Physics, Kyung Hee University, <sup>2</sup>Institute of Materials Science, Vietnam Academy of Science and Technology</p>
WP-090	<p><b>LPCVD SiO<sub>2</sub> 기반 High–k–Free MIS–HEMT의 DC/AC 특성 평가</b></p> <p>김대강, 손보성, 김희진, 이성민, 이왕엽, 박시현</p> <p>영남대학교 전자공학과</p>
WP-091	<p><b>Monolithic GaN CMOS Integration with N/P–Channel FETs</b></p> <p>Seung–Su Kim and Ho–Young Cha</p> <p>School of Electronic and Electrical Engineering, Hongik University</p>
WP-092	<p><b>Study on Al/Ni/W Multilayer for Simultaneous Ohmic Contact to n– and p–type 4H–SiC</b></p> <p>Jun Hyun Byun<sup>1</sup> and Dae Hwan Kang<sup>2</sup></p> <p><sup>1</sup>Department of Materials Science &amp; Engineering, POSTECH, <sup>2</sup>Department of Semiconductor Engineering, POSTECH</p>
WP-093	<p><b>Scaling Behavior of On–State Characteristics in Power GaN HEMTs</b></p> <p>Ji–Seung Seo, Jin–Sup Kim, and Hyeon–Bhin Jo</p> <p>KETI</p>



WP-094	<p><b>Characterization of Surface Stability in Cap-Recessed InP HEMTs Grown by MOCVD</b></p> <p>Geunuk Han, Yunji Jeong, Inseon Song, Kyutae Kim, Keunman Song, Jaephil Shim, and Hyunchul Jang</p> <p>KANC</p>
WP-095	<p><b>Design Optimization and Electrical Characterization of a Two-Step Ion Implanted Non-Box JFET Doping Profile in 1.2-kV SiC MOSFETs</b></p> <p>Hee-Jin Kim and Ho-Jun Lee</p> <p>Department of Electrical and Electronics Engineering, Pusan National University</p>
WP-096	<p><b>Integration of an Active Miller-Clamp and Inverter-Assisted Driver for Reduced Switching Loss in GaN HEMTs</b></p> <p>Dong-Ho Seo and Ho-Young Cha</p> <p>School of Electronic and Electrical Engineering, Hongik University</p>
WP-097	<p><b>A Study on the Dependence of Device Dimension on Quasi-Vertical GaN Schottky Barrier Diodes</b></p> <p>Seongmin Kang, Jinseop Kim, and Hyeon-Bhin Jo</p> <p>KETI</p>
WP-098	<p><b>Impact of Side-Recess Length on the DC and RF Characteristics of GaAs Metamorphic High Electron Mobility Transistors (mHEMTs)</b></p> <p>Inseon Song<sup>1</sup>, Ilhyeong Lee<sup>1</sup>, Kyutae Kim<sup>1</sup>, Geunuk Han<sup>1</sup>, Yunji Jeong<sup>1</sup>, Seung Heon Shin<sup>2</sup>, Eun-Kyung Chu<sup>1</sup>, Deok-Soo Park<sup>1</sup>, Yumin Koh<sup>1</sup>, Hyunchul Jang<sup>1</sup>, and Jae-Phil Shim<sup>1</sup></p> <p><sup>1</sup>KANC, <sup>2</sup>Soonchunhyang University</p>
WP-099	<p><b>Modulation of 2DEG for Highly Sensitive Magnetic Field Detection</b></p> <p>Cheng Han<sup>1</sup>, Mingi Seo<sup>1</sup>, Younghoon Kim<sup>1</sup>, John Son<sup>3</sup>, and Junseok Heo<sup>1,2</sup></p> <p><sup>1</sup>Department of Intelligence Semiconductor Engineering, Ajou University,</p> <p><sup>2</sup>Department of Electrical and Computer Engineering, Ajou University,</p> <p><sup>3</sup>Genicom Co., Ltd</p>
WP-100	<p><b>CMOS Compatible SiGe Channel Photo BJT with High Responsivity and Efficiency</b></p> <p>Tae Young Yoon, Tae Woo Kim, Dong-Woo Jee, and Jang Hyun Kim</p> <p>Department of Intelligence Semiconductor Engineering, Ajou University</p>



WP-101	<p><b>Electrical Characteristics Dependence on Gate-Drain Spacing for 1200 V-Class Applications of E-Mode GaN on Si Power Devices</b></p> <p>Arim Choi, Hoseok Yoo, Hyeok-Jun Lee, Minjoo Kim, Chuyoung Cho, and Dong-Hyun Kim KANC</p>
WP-102	<p><b>AlGaN/GaN HEMT 소자의 절연막 형성 및 열처리에 따른 전기적 특성 변화</b></p> <p>김민주, 최아림, 유호석, 이혁준, 조주영, 김동현 한국나노기술원</p>
WP-103	<p><b>6인치 Si 기판 기반 pGaN/Al<sub>0.2</sub>Ga<sub>0.8</sub>N/GaN HEMT의 게이트 금속에 따른 전기적 특성 비교</b></p> <p>이혁준, 최아림, 유호석, 김민주, 조주영, 김동현 한국나노기술원</p>
WP-104	<p><b>Optimization of Passivation Structures for High-Reliability GaN HEMT Operation</b></p> <p>Hoil Son<sup>1</sup>, Donghan Kim<sup>1</sup>, Junghee Lee<sup>3</sup>, Haechan Lee<sup>1</sup>, Hyeongwoo Lee<sup>1</sup>, Jeongil Kim<sup>2</sup>, and Hongsik Park<sup>1</sup></p> <p><sup>1</sup>School of Electronic and Electrical Engineering, Kyungpook National University, <sup>2</sup>Department of Semiconductor Engineering, Dong-A University, <sup>3</sup>L&amp;D Inc.</p>
WP-105	<p><b>E-Mode Power GaN HEMT 구동을 위한 GaN 기반 모노리식 게이트 드라이브 회로 설계 및 제작</b></p> <p>임진홍<sup>1,2</sup>, 김동훈<sup>2</sup>, 임준혁<sup>2</sup>, 김종선<sup>2</sup>, 차호영<sup>1,2</sup></p> <p><sup>1</sup>주식회사 칩스케이, <sup>2</sup>홍익대학교</p>
WP-106	<p><b>Single Event Effects (SEE) Analysis and Radiation Resistance Evaluation of AlGaN/GaN HEMTs Devices by Alpha Particles</b></p> <p>Soomin Kim<sup>1</sup>, Dongwook Kim<sup>1</sup>, Dongchan Kim<sup>2</sup>, and Jongwook Jeon<sup>2</sup></p> <p><sup>1</sup>Department of Display Engineering, Sungkyunkwan University, <sup>2</sup>Department of Electronic and Electric Engineering, Sungkyunkwan University</p>
WP-107	<p><b>Low-Temperature Passivation of In<sub>0.53</sub>Ga<sub>0.47</sub>As/InP Mesa-Type Photodiodes</b></p> <p>Taekyun Kim<sup>1</sup> and Junseok Heo<sup>1,2</sup></p> <p><sup>1</sup>Department of Intelligent Semiconductor Engineering, Ajou University, <sup>2</sup>Department of Electrical and Computer Engineering, Ajou University</p>



WP-108	<p><b>Effect of Diode Electrode Structure on the Efficiency of Betavoltaic Cells</b></p> <p>Jaewon Park<sup>1,2</sup>, Hyeon-Tak Kwak<sup>1</sup>, Dong-Seok Kim<sup>3</sup>, Hoe-Min Kwak<sup>1</sup>, Huiyun Jung<sup>1</sup>, Donghan Kim<sup>2</sup>, Dong-Young Kim<sup>1</sup>, Jeong-Gil kim<sup>4</sup>, Hongsik Park<sup>2</sup>, Sung-Bum Bae<sup>1</sup>, and Hyung-Seok Lee<sup>1</sup></p> <p><sup>1</sup>ETRI, <sup>2</sup>School of Electronic and Electrical Engineering, Kyungpook National University, <sup>3</sup>Korea Multi-Purpose Accelerator Complex, KAERI, <sup>4</sup>Department of Semiconductor, Dong-A University</p>
WP-109	<p><b>Multi-Threshold Voltage GaN Device Development for GaN-Based Power ICs on a 200mm GaN-on-Si</b></p> <p>Junhyeok Lee, Min Su Cho, Nakwon Yu, Jihoun Jung, Minjae Yeom, Heesub Lee, Jonghyun Lee, Sanggi Lee, and Woochul Jeon</p> <p>DB HiTek</p>
WP-110	<p><b>AlGaN/GaN의 금속 접합 열처리 시간에 따른 계면 반응 및 구조 분석</b></p> <p>최여진<sup>1</sup>, 장승환<sup>1</sup>, 박찬영<sup>1</sup>, 안대규<sup>1</sup>, 최다은<sup>1</sup>, 임기식<sup>2</sup>, 안성진<sup>1</sup></p> <p><sup>1</sup>국립금오공과대학교 신소재공학과, <sup>2</sup>한국폴리텍대학</p>
WP-111	<p><b>AlGaN/GaN 기반 비대칭 MSM 광검출기</b></p> <p>홍성호<sup>1</sup>, 허준석<sup>2</sup></p> <p><sup>1</sup>아주대학교 전자공학과, <sup>2</sup>아주대학교 지능형반도체공학과</p>
WP-112	<p><b><math>\beta</math>-Ga<sub>2</sub>O<sub>3</sub> 기반 수직형 SBD를 활용한 저선량 X선 검출기</b></p> <p>김선재<sup>1,3</sup>, 뷔호영<sup>1,2</sup>, 김형윤<sup>3</sup>, 박지현<sup>3</sup>, 전대우<sup>3</sup>, 황완식<sup>1,2</sup></p> <p><sup>1</sup>한국항공대학교 신소재공학과, <sup>2</sup>한국항공대학교 스마트항공모빌리티학과, <sup>3</sup>한국세라믹 기술원</p>
WP-113	<p><b>Monolithic Integration of a GaAs VCSELs on a Si Photodiodes for Coaxial Time-of-Flight Sensing</b></p> <p>Wonjun Cho<sup>1</sup> and Junseok Heo<sup>1,2</sup></p> <p><sup>1</sup>Department of Intelligence Semiconductor Engineering, Ajou University, <sup>2</sup>Department of Electrical and Computer Engineering, Ajou University</p>
WP-114	<p><b>Evaluation of Contact Properties of AlGaN/GaN High-Electron-Mobility Transistor Using the Bridge-Contact Resistance Method</b></p> <p>Bogeun Son, Hyunjung Lee, and Hongsik Park</p> <p>School of Electronic and Electrical Engineering, Kyungpook National University</p>



WP-115	<p><b>Fabrication of 4-Inch AlGaN/GaN HEMT on SiC for RF Application</b></p> <p>Raksan Ko, Dong-Hyun Kim, Deoksoo Park, and Jaemoo Kim Device Technology Division, KANC</p>
WP-116	<p><b>High Breakdown Voltage for Vertical GaN PN Diode with Multi Step Mesa Junction Termination Extensions</b></p> <p>Dae-Hyun Son<sup>1</sup>, Donghan Kim<sup>1</sup>, Jaewon Park<sup>1,2</sup>, Huiyun Jung<sup>2</sup>, Hyeon-Tak Kwak<sup>2</sup>, Hoe-Min Kwak<sup>2</sup>, Hongsik Park<sup>1</sup>, Sung-Bum Bae<sup>2</sup>, and Hyung-Seok Lee<sup>2</sup></p> <p><sup>1</sup>School of Electronic and Electrical Engineering, Kyungpook National University, <sup>2</sup>ETRI</p>
WP-117	<p><b>Experimental Study on i-GaN Thickness Effects in GaN PiN Betavoltaic Cell Performance</b></p> <p>Huiyun Jung<sup>1</sup>, Jae-Won Park<sup>1,2</sup>, Hyeon-Tak Kwak<sup>1</sup>, Donghan Kim<sup>2</sup>, Hoe-Min Kwak<sup>1</sup>, Dong-Young Kim<sup>1</sup>, Dong-Seok Kim<sup>3</sup>, Jeong-Gil Kim<sup>4</sup>, Hongsik Park<sup>2</sup>, Sung-Bum Bae<sup>1</sup>, and Hyung-Seok Lee<sup>1</sup></p> <p><sup>1</sup>Photonic/Wireless Devices Research Division, Thin GaN Materials &amp; Device Creative Research Section, ETRI, <sup>2</sup>School of Electronic and Electrical Engineering, Kyungpook National University, <sup>3</sup>KAERI, <sup>4</sup>Dong-A University</p>
WP-118	<p><b>Electrical Characteristics Analysis of GaN HEMTs with p-GaN Gate Depending on RTA Temperature</b></p> <p>Yeonsil Yang, Jinseop Kim, and Hyeon-Bhin Jo ICT Device and Packaging Center, KETI</p>
WP-119	<p><b>Ga<sub>2</sub>O<sub>3</sub>의 UVC 검출 특성을 활용한 불꽃감지센서 응용 가능성</b></p> <p>류희중<sup>1,2</sup>, 김선재<sup>2</sup>, 엄준성<sup>3</sup>, 구희성<sup>3</sup>, 박지현<sup>4</sup>, 전대우<sup>4</sup>, 황완식<sup>1,2</sup></p> <p><sup>1</sup>한국항공대학교 스마트항공모빌리티학과, <sup>2</sup>한국항공대학교 신소재공학과, <sup>3</sup>(주)엠스, <sup>4</sup>한국세라믹기술원</p>
WP-120	<p><b>Reliability Enhancement of GaN MIS-HEMTs via High-Pressure Annealing</b></p> <p>Songyi Han and Dae-Myeong Geum Department of Electrical and Computer Engineering, Inha University</p>



WP-121	<p><b>Influence of CuO<sub>x</sub> Radius on Breakdown Voltage of p-Type CuO<sub>x</sub> / n-Type <math>\beta</math>-Ga<sub>2</sub>O<sub>3</sub> Heterojunction Diodes</b></p> <p>Hyeon Cheol Kim<sup>1</sup>, Sameer Pokhrel<sup>1</sup>, V. Janardhanam<sup>2</sup>, Chel-Jong Choi<sup>1</sup>, and Kyu Hwan Shim<sup>1,3</sup></p> <p><sup>1</sup>School of Semiconductor and Chemical Engineering, Semiconductor Physics Research Center (SPRC), Jeonbuk National University, <sup>2</sup>Department of Physics, School of Engineering, Dayananda Sagar University, <sup>3</sup>R&amp;D Division, Sigetronics, Inc.</p>
WP-122	<p><b>p-GaN Gate Recessed GaN HEMT with MIS Structure</b></p> <p>Jong-Hyeok Sim, Jinhyeong Park, and Ho-Young Cha</p> <p>School of Electronic and Electrical Engineering, Hongik University</p>
WP-123	<p><b>Photodiode based on Ga<sub>2</sub>O<sub>3</sub> Nanowire Catalyst Synthesis</b></p> <p>Jung-Bok Lee, Min-Seok Jang, Hee-Jin Kim, Ju-Eun An, and Ho-Jun Lee</p> <p>Pusan National University</p>
WP-124	<p><b>p-GaN AlGaN/GaN HEMT의 정확한 열화시험을 위한 소자특성 실시간 측정 최적화</b></p> <p>이서윤, 김형탁</p> <p>홍익대학교 전자전기공학부</p>
WP-125	<p><b>Femtosecond Mid-Infrared Cr:ZnS Laser Utilizing Graphene-ZnSe Saturable Absorber</b></p> <p>Seong Hyeon Kim<sup>1</sup>, Seung Tae Song<sup>1</sup>, Sang Yeop Jeong<sup>1</sup>, Dong Ho Shin<sup>2</sup>, Young Tea Chun<sup>1</sup>, Fabian Rotermund<sup>3</sup>, and Won Bae Cho<sup>1</sup></p> <p><sup>1</sup>Department of Nano-Semiconductor Engineering, Korea Maritime &amp; Ocean University, <sup>2</sup>Digital Biomedical Research Division, ETRI, <sup>3</sup>Department of Physics, KAIST</p>
WP-126	<p><b>E-Mode AlGaN HEMTs Enabled by Polarization Engineering with p-AlGaN Cap Layers</b></p> <p>Ju-Eun Yun, Ryeong-Eun Kim, Do-Hyung Yeo, and Ho-Young Cha</p> <p>School of Electronic and Electrical Engineering, Hongik University</p>



WP-127	<p>Contact-Area Engineering Using Patterned Anode Structures in Vertical GaN PIN Diode Min-Guk Han and Ho-Young Cha School of Electronic and Electrical Engineering, Hongik University</p>
WP-384	<p>High-Efficiency X-Band AlGaN/GaN/AlN HEMTs Achieving 64.2 % PAE and 6.27 W/mm CW Output Power Density Donghan Kim<sup>1</sup>, Jung-Hee Lee<sup>3</sup>, A-Hyun Lee<sup>2</sup>, Jeong-Gil Kim<sup>2</sup>, and Hongsik Park<sup>1</sup> <sup>1</sup>School of Electronic and Electrical Engineering, Kyungpook National University, <sup>2</sup>Department of Semiconductor, Dong-A University, <sup>3</sup>L&amp;D Inc.</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE1 (4층, 로비)

## [WP] 포스터세션

### F. Silicon and Group-IV Devices and Integration Technology 분과

WP-128	<p><b>A Study on the Reversed Thickness Dependence of the Memory Window in HZO-Based MIFIS FeFETs</b></p> <p>Kilhwa Pi<sup>1,2</sup>, Min Kyu Yeom<sup>1,2</sup>, Seungheon Choi<sup>1,2</sup>, Sanghyup Lee<sup>1,2</sup>, and Cheol Seong Hwang<sup>1,2</sup></p> <p><sup>1</sup>Department of Materials Science and Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>
WP-129	<p><b>Development of Process Technology for 180 nm CMOS Multi-Project Wafer (MPW) Service</b></p> <p>Byeong-Hyeok Choi<sup>1</sup>, Sung-Min Park<sup>1</sup>, Jin Hyun Kim<sup>1</sup>, Eunpa Won<sup>1</sup>, Joong-Heon Kim<sup>1</sup>, Daeyoung Kim<sup>1</sup>, Juyoung An<sup>1</sup>, Sangsoo Kim<sup>1</sup>, Onyu Kim<sup>1</sup>, Hyosang Kim<sup>1</sup>, Changweon Lee<sup>1</sup>, Joongsool Park<sup>1</sup>, Youngsu Kim<sup>2</sup>, and Sang Hyun Jung<sup>1</sup></p> <p><sup>1</sup>KANC, <sup>2</sup>NNFC</p>
WP-130	<p><b>Fully CMOS-Compatible Analog Content-Addressable Memory Using Single-Poly Embedded Flash Memory</b></p> <p>Jeseung Jeong<sup>1,2</sup>, Jonghyun Ko<sup>1,2</sup>, Wooseong Roh<sup>1,2</sup>, Jong-Ho Lee<sup>1,2</sup>, and Gyuweon Jung<sup>1,2,3</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University, <sup>3</sup>School of Transdisciplinary Innovations, Seoul National University</p>
WP-131	<p><b>Separating Ferroelectric Negative Capacitance from High-k Contributions in Metal-Ferroelectric-Insulator-Semiconductor Structured Capacitor</b></p> <p>Subin Jung<sup>1,2</sup>, Seungheon Choi<sup>1,2</sup>, and Cheol Seong Hwang<sup>1,2</sup></p> <p><sup>1</sup>Department of Materials Science and Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>



WP-132	<p><b>Random Telegraph Noise-Driven Probabilistic Bit in Polycrystalline Silicon Thin-Film Transistor</b> Jun-Young Park, Seong-Hun Kim, and Joon-Kyu Han Department of Material Science and Engineering, Seoul National University</p>
WP-133	<p><b>Modeling and Process Design Guideline of Oxide Chemical Mechanical Planarization in CMOS Back-End-of-Line Process</b> Min Seok Cha<sup>1,2</sup> and Woo Young Choi<sup>1,2</sup> <sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>
WP-134	<p><b>Integration and Validation of a Multi-Chip Floorplan with Process Monitoring on a 180nm CMOS MPW Platform</b> Eunpa Won<sup>1</sup>, Sung-Min Park<sup>1</sup>, Jin Hyun Kim<sup>1</sup>, Byeong-Hyeok Choi<sup>1</sup>, Joong-Heon Kim<sup>1</sup>, Daeyoung Kim<sup>1</sup>, Juyoung An<sup>1</sup>, Sangsoo Kim<sup>1</sup>, Onyu Kim<sup>1</sup>, Hyosang Kim<sup>1</sup>, Changweon Lee<sup>1</sup>, Joongsool Park<sup>1</sup>, Youngsu Kim<sup>2</sup>, and Sang Hyun Jung<sup>1</sup> <sup>1</sup>KANC, <sup>2</sup>NNFC</p>
WP-135	<p><b>Annealing 온도에 따른 피드백 전계효과 트랜지스터 기반 확률 비트의 특성 변화 연구</b> 허효주, 조경아, 김상식 고려대학교 전기전자공학과</p>
WP-136	<p><b>트리플 게이트 피드백 전계효과 트랜지스터로 구성된 로직-인-메모리 셀의 JK Latch 동작 연구</b> 설민혁, 조경아, 김상식 고려대학교 전기전자공학과</p>
WP-137	<p><b>Probabilistic Bit와 Markov Random Fields Model을 이용한 Image Denoising 연구</b> 강민구, 조경아, 김상식 고려대학교 전기전자공학과</p>
WP-138	<p><b>삼중 게이트 피드백 전계효과 트랜지스터로 구성된 로직-인-메모리 셀의 3진법 NAND Gate 동작 연구</b> 김태완<sup>1</sup>, 허효주<sup>1</sup>, 전주희<sup>1</sup>, 김동기<sup>2</sup>, 이동형<sup>2</sup>, 조경아<sup>1</sup>, 김상식<sup>1,2</sup> <sup>1</sup>고려대학교 전기전자공학과, <sup>2</sup>고려대학교 반도체시스템공학과</p>



WP-139	<p>삼중 게이트 피드백 전계효과 트랜지스터 기반 NANY/NCONS 게이트의 로직-인-메모리 동작 연구</p> <p>전윤수<sup>1</sup>, 임재욱<sup>1</sup>, 전주희<sup>2</sup>, 조경아<sup>2</sup>, 김상식<sup>1,2</sup></p> <p><sup>1</sup>고려대학교 반도체시스템공학과, <sup>2</sup>고려대학교 전기전자공학과</p>
WP-140	<p>Scaling Characteristics of Oxide-Based Vertical Channel Transistors for Gain-Cell Memory</p> <p>Hyeonho Gu<sup>1</sup>, Haksoon Jung<sup>1</sup>, Minho Park<sup>1</sup>, Hyeonjin Lee<sup>2</sup>, Yanfeng Zhao<sup>2</sup>, Yongwoo Lee<sup>1</sup>, Byungjo Kim<sup>2</sup>, and Jimin Kwon<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical Engineering, UNIST, <sup>2</sup>Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p>
WP-141	<p>p-Si:H/n-Ga<sub>2</sub>O<sub>3</sub> 이중 채널 기반 생체모방 시냅스 광 트랜지스터</p> <p>김용기<sup>1</sup>, 윤영빈<sup>3</sup>, 신명훈<sup>1,2</sup></p> <p><sup>1</sup>한국항공대학교 항공전자정보공학부, <sup>2</sup>한국항공대학교 우주시스템공학부, <sup>3</sup>한국전자통신연구원 차세대반도체소자연구실</p>
WP-142	<p>Resistivity–Correlated Design of Zero-TCR Poly-Si Resistors From 130 nm to 28 nm HKMG CMOS Process</p> <p>Seungjun Boo, Jinyuk Lee, Jonghyun Son, Dongmin Shin, Juri Kim, Changmin Jeon, and Ohkyum Kwon</p> <p>Samsung Foundry, Samsung Electronics Co., Ltd.</p>
WP-143	<p>Layered Trench Gate Exhibiting Source/Drain Over-Etch Immunity without Punch-Through Stopper</p> <p>Seungjoon Jeong and Changhwan Shin</p> <p>School of Electrical Engineering, College of Engineering, Korea University</p>
WP-144	<p>Optimized FlipFET Standard Cell Design for Reduced Gate Delay and Improved Routability</p> <p>Dongjin Wi<sup>1</sup>, Minho Park<sup>1</sup>, and Jimin Kwon<sup>2</sup></p> <p><sup>1</sup>Department of Electrical Engineering, UNIST, <sup>2</sup>Department of Electrical Engineering, Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p>
WP-145	<p>Analysis of Gate-All-Around FET with Oxide Bottom-Up Structure to Reduce Parasitic Capacitance in Shallow Trench Isolation Region</p> <p>Sungho Yang and Changhwan Shin</p> <p>School of Electrical Engineering, College of Engineering, Korea University</p>



WP-146	<p><b>Effect of Annealing Atmosphere for Bottom Electrode Anneal on the Endurance of W/HZO/W Ferroelectric Capacitors</b> Hyeonjung Park<sup>1</sup>, Changwoo Han<sup>2</sup>, and Changhwan Shin<sup>2</sup> <sup>1</sup>Department of Electrical and Computer Engineering, Sungkyunkwan University, <sup>2</sup>School of Electrical Engineering, College of Engineering, Korea University</p>
WP-147	<p><b>Characteristics of GIDL Erase-Induced Hot Carrier Injection in Vertical NAND Flash Memory</b> Jae Hyun Nam<sup>1,2</sup>, Jin Ho Chang<sup>1,2</sup>, Kyung Moon Kim<sup>1,2</sup>, Da Eun Yang<sup>1,2</sup>, Ji Sun Baek<sup>1,2</sup>, Suk-Kang Sung<sup>3</sup>, and Woo Young Choi<sup>1,2</sup> <sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University, <sup>3</sup>Advanced Flash Technology Team, Samsung Electronics Co., Ltd.</p>
WP-148	<p><b>Latch-Up Voltage Modulation by Applying Adaptive Pulse on Charge-Trap Based Floating-Body Transistor</b> Taeho Lee<sup>1,2</sup>, Jonghyun Ko<sup>1,2</sup>, Jiseong Im<sup>1,2</sup>, and Jong-Ho Lee<sup>1,2</sup> <sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>
WP-149	<p><b>Inner Spacer Effects on Stress and Parasitic Capacitance in Gate-All-Around Nanosheet FETs: A TCAD Framework Using Kinetic Monte Carlo Epitaxy</b> NaYun Kim<sup>1,2</sup> and Jiwon Chang<sup>1,2</sup> <sup>1</sup>Department of System Semiconductor Engineering, Yonsei University, <sup>2</sup>BK21 Graduate Program in Intelligent Semiconductor Technology</p>
WP-150	<p><b>Additional Oxidation Treatment를 통한 5V NMOS TDDB 개선</b> 황수진, 강형근, 이도현, 김선구, 남명희, 박정수 Department of Technology Development, SK hynix systemic (wuxi) solutions, Co., Ltd.</p>
WP-151	<p><b>3-Tier CFET 6T-SRAM With 2D-TMDCs Channels With Double -Sided Interconnect and Backside PDN for Angstrom Technology Node</b> Jonghun Lee<sup>1</sup>, Seungmin Jun<sup>2</sup>, and Jongwook Jeon<sup>2</sup> <sup>1</sup>Department of Display Engineering, Sungkyunkwan University, <sup>2</sup>Department of Electrical and Computer Engineering, Sungkyunkwan University</p>



WP-152	<p><b>Enhanced Electrical Performance of GOI nMOSFETs via Laser-Annealing-Induced Source/Drain Activation and Tensile Strain</b></p> <p>Minseo Song<sup>1</sup>, Hojin Jeong<sup>2</sup>, Hyeongrak Lim<sup>2</sup>, and Sanghyeon Kim<sup>2</sup></p> <p><sup>1</sup>Graduate School of Semiconductor Technology, KAIST, <sup>2</sup>School of Electrical Engineering, KAIST</p>
WP-153	<p><b>From Vulnerability to Robustness: Radiation-Hard Isolation for BPR-Enabled Stacked Nanosheet CFETs</b></p> <p>Dongwook Kim<sup>1</sup>, Sumin Kim<sup>1</sup>, and Jongwook Jeon<sup>2</sup></p> <p><sup>1</sup>Department of Display Engineering, Sungkyunkwan University, <sup>2</sup>Department of Electrical and Computer Engineering, Sungkyunkwan University</p>
WP-154	<p><b>Enhanced Responsivity of CuInSe<sub>2</sub> Quantum Dot-Coated Silicon Photodetectors</b></p> <p>Juwon Yun<sup>1</sup>, Neunghee Han<sup>2</sup>, Seonyoung Park<sup>1</sup>, Jihun Lee<sup>1</sup>, Woonhyuk Baek<sup>3</sup>, and Kihyun Kim<sup>1,4</sup></p> <p><sup>1</sup>Department of Electronics and Information Engineering, Jeonbuk National University, <sup>2</sup>Department of Semiconductor Science and Technology, Jeonbuk National University, <sup>3</sup>School of Semiconductor and Chemical Engineering, Jeonbuk National University, <sup>4</sup>Division of Electronic Engineering, Jeonbuk National University</p>
WP-155	<p><b>Frequency-Tunable THz Detector Design with Embedded Varactor Stacking for Detecting Sensitivity</b></p> <p>Gi Yong Lee<sup>1</sup>, Yoo Bin Song<sup>1,3</sup>, Tae Hwan Hyeon<sup>2</sup>, Min Woo Ryu<sup>1,3</sup>, and Kyung Rok Kim<sup>1,3</sup></p> <p><sup>1</sup>Department of Electrical Engineering, UNIST, <sup>2</sup>Graduate School of Semiconductor Materials and Devices Engineering, UNIST, <sup>3</sup>Ternell Corp.</p>
WP-156	<p><b>A 28-nm Ternary-SRAM Macro with Highly Bit-Dense Bitline Reduction Architecture and Energy-Efficient Single-Ended 8T Access Operation</b></p> <p>Myoung Kim<sup>1,2</sup>, Yesong Jeong<sup>1,2</sup>, Woo-Seok Kim<sup>1</sup>, Junyoung Park<sup>1</sup>, Sang Hun Yeo<sup>1</sup>, In Jun Jang<sup>1</sup>, Kwan Yong Lee<sup>2</sup>, Min Woo Ryu<sup>1,2</sup>, and Kyung Rok Kim<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical Engineering, UNIST, <sup>2</sup>Ternell Corp.</p>



WP-157	<p><b>Development of a Next-Generation CFET PDK Considering Backside Power Delivery Network (BSPDN)</b></p> <p>JuneYeop Lee<sup>1</sup>, Jihye Yoo<sup>1</sup>, Gaon Lee<sup>2</sup>, and Jongwook Jeon<sup>1</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, Sungkyunkwan University, <sup>2</sup>Department of Display Engineering, Sungkyunkwan University</p>
WP-158	<p><b>Enhancing Sensitivity of FET-Based Trantenna through Aperture Design</b></p> <p>Tae Hwan Hyeon<sup>1</sup>, Yoo Bin Song<sup>2,3</sup>, Gi Yong Lee<sup>2</sup>, Min Woo Ryu<sup>2,3</sup>, and Kyung Rok Kim<sup>2,3</sup></p> <p><sup>1</sup>Graduate School of Semiconductor Materials and Devices Engineering, UNIST, <sup>2</sup>Department of Electrical Engineering, UNIST, <sup>3</sup>Ternell Corp.</p>
WP-159	<p><b>Transparent Optical Power Monitoring Using Thin InGaAs Membrane MSM Photodetector</b></p> <p>Jaehyeon An<sup>1,2</sup>, Jinil Lee<sup>1</sup>, Kyunghwan Kim<sup>1</sup>, Hojoong Jung<sup>1</sup>, Jae-Hoon Han<sup>1</sup>, SangWook Han<sup>1</sup>, Myung-Jae Lee<sup>2</sup>, and DaeHwan Ahn<sup>1</sup></p> <p><sup>1</sup>Center for Quantum Technology, KIST, <sup>2</sup>Department of Electrical and Electronic Engineering, Yonsei University</p>
WP-160	<p><b>An Area-Efficient TCAM Cell Based Ternary Latch with Hybrid Operation</b></p> <p>Jun Young Park<sup>1</sup>, Woo-Seok Kim<sup>1</sup>, Myoung Kim<sup>1,2</sup>, Yesong Jeong<sup>1</sup>, Sang Hun Yeo<sup>1</sup>, Kwan Yong Lee<sup>1</sup>, In Jun Jang<sup>1</sup>, Min Woo Ryu<sup>1,2</sup>, and Kyung Rok Kim<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical Engineering, UNIST, <sup>2</sup>Ternell Corp.</p>
WP-161	<p><b>Study of Tensile Strain Formation in Rapid-Melting-Growth Germanium under Different SiO<sub>2</sub> Capping Conditions</b></p> <p>Dong Woo Lee, Jongmin Son, Hyeseo Park, Youngmin Kim, and Donghwan Ahn</p> <p>School of Materials Science &amp; Engineering, Kookmin University</p>
WP-162	<p><b>Tunneling-Based 3D Ternary CMOS Technology for Highly Reliable, Low-Power, and High-Density SRAM Toward Sustainable SoC Design</b></p> <p>Woo-Seok Kim<sup>1</sup>, Sang Hun Yeo<sup>1</sup>, Kwan Yong Lee<sup>2</sup>, Myoung Kim<sup>1,2</sup>, In Jun Jang<sup>1</sup>, Junyoung Park<sup>1</sup>, Yesong Jeong<sup>1,2</sup>, Min Woo Ryu<sup>1,2</sup>, and Kyung Rok Kim<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical Engineering, UNIST, <sup>2</sup>Ternell Corp.</p>



WP-163	<p><b>TCAD-Based Variability Analysis and Optimization in 28-nm Gate-Underlap Ternary CMOS Technology</b></p> <p>Kwan Yong Lee<sup>1</sup>, Woo-Seok Kim<sup>2</sup>, Sang Hun Yeo<sup>2</sup>, In Jun Jang<sup>2</sup>, Myoung Kim<sup>1,2</sup>, Yesong Jeong<sup>1,2</sup>, Junyoung Park<sup>2</sup>, Min Woo Ryu<sup>1,2</sup>, and Kyung Rok Kim<sup>1,2</sup></p> <p><sup>1</sup>Ternell Corp., <sup>2</sup>Department of Electrical Engineering, UNIST</p>
WP-164	<p><b>Ultra-Thin La<sub>2</sub>O<sub>3</sub> Interfacial Layer for TDDB Lifetime Extension in HZO Ferroelectric Devices</b></p> <p>HyeonCheol Jeong<sup>1</sup>, KyungSoo Park<sup>2</sup>, Yoonseok Lee<sup>1</sup>, Yeonwoo Choi<sup>1</sup>, SangMyun Lim<sup>1</sup>, JiHoon Choi<sup>1</sup>, Taesuk Kim<sup>2</sup>, and Changhwan Choi<sup>1,2</sup></p> <p><sup>1</sup>Department of Semiconductor Engineering, Hanyang University, <sup>2</sup>Division of Materials Science and Engineering, Hanyang University</p>
WP-165	<p><b>Short-Channel Effect Immune and Ultra-Low Power Steep-Slope Ternary CFET/GAA Architecture for Edge-AI Applications</b></p> <p>Sang Hun Yeo<sup>1</sup>, Woo-Seok Kim<sup>1</sup>, Kwan Yong Lee<sup>2</sup>, In Jun Jang<sup>1</sup>, Myoung Kim<sup>1,2</sup>, Jun Young Park<sup>1</sup>, Yesong Jeong<sup>1,2</sup>, Min Woo Ryu<sup>1,2</sup>, and Kyung Rok Kim<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical Engineering, UNIST, <sup>2</sup>Ternell Corp.</p>
WP-166	<p><b>Bias-Temperature Instability Characteristics of High-k Metal Gate Ternary CMOS Technology</b></p> <p>In Jun Jang<sup>1</sup>, Woo-Seok Kim<sup>1</sup>, Sang Hun Yeo<sup>1</sup>, Kwan Yong Lee<sup>2</sup>, Myoung Kim<sup>1,2</sup>, Junyoung Park<sup>1</sup>, Yesong Jeong<sup>1,2</sup>, Min Woo Ryu<sup>1,2</sup>, and Kyung Rok Kim<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical Engineering, UNIST, <sup>2</sup>Ternell Corp.</p>
WP-167	<p><b>Protocol-Compatible Ternary Bus for Energy-Efficient On-Chip Interconnects</b></p> <p>Yesong Jeong<sup>1,2</sup>, Myoung Kim<sup>1,2</sup>, Woo-Seok Kim<sup>1</sup>, Jun Young Park<sup>1</sup>, Sang Hun Yeo<sup>1</sup>, Kwan Yong Lee<sup>2</sup>, In Jun Jang<sup>1</sup>, Min Woo Ryu<sup>1,2</sup>, and Kyung Rok Kim<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical Engineering, UNIST, <sup>2</sup>Ternell Corp.</p>
WP-168	<p><b>High-Speed Terahertz Detector for Large-Area Low-Noise Imaging System</b></p> <p>Yoo Bin Song<sup>1,3</sup>, Tae Hwan Hyeun<sup>2</sup>, Gi Yong Lee<sup>1</sup>, Min Woo Ryu<sup>1,3</sup>, and Kyung Rok Kim<sup>1,3</sup></p> <p><sup>1</sup>Department of Electrical Engineering, UNIST, <sup>2</sup>Graduate School of Semiconductor Materials and Devices Engineering, UNIST, <sup>3</sup>Ternell Corp.</p>



WP-169	<p><b>Compact Modeling of CFET Devices Including N/PMOS and Intermediate RC Network</b> Gaon Lee<sup>1</sup>, Hojin Kim<sup>3</sup>, Woonwoo Kim<sup>2</sup>, Jihye Yoo<sup>4</sup>, Junyeop Lee<sup>4</sup>, and Jongwook Jeon<sup>2</sup> <sup>1</sup>Department of Display Engineering, Sungkyunkwan University, <sup>2</sup>Department of Electrical and Computer Engineering, Sungkyunkwan University, <sup>3</sup>Department of Semiconductor Convergence Engineering, Sungkyunkwan University, <sup>4</sup>Device Research Laboratory (SKKU-DRL), Sungkyunkwan University</p>
WP-170	<p><b>Impact of Doping Concentration in the Lightly-Doped Drain on Gate-Induced Drain Leakage of Ultra-Thin-Body MOSFET</b> Erica Soomin Kim<sup>1,2</sup> and Seongjae Cho<sup>1,2</sup> <sup>1</sup>Division of Electronic and Semiconductor Engineering, Ewha Womans University, <sup>2</sup>Institute for Multiscale Matter and Systems (IMMS), Ewha Womans University</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE1 (4층, 로비)

## [WP] 포스터세션

### M. RF and Wireless Design 분과

WP-191	<p><b>3D-Printed AiP Lid Substrates with Coaxial Through-Via Feeds for Improved High-Frequency Signal Integrity</b> Kyungsun Kim<sup>1</sup>, Nahyeon Kim<sup>1</sup>, Haksoon Jung<sup>2</sup>, Yongwoo Lee<sup>2</sup>, and Jimin Kwon<sup>1,2</sup> <sup>1</sup>Graduate School of Semiconductor Materials and Devices Engineering, UNIST, <sup>2</sup>Department of Electrical Engineering, UNIST</p>
WP-192	<p><b>A Bandgap-Referenced Wide-Swing Current-Mode VCSEL Driver in 0.18-<math>\mu</math>m CMOS for Low-Cost Short-Range LiDAR Sensors</b> Yiyao Li, Yu Hu, Sieun Choi, Suwon Cho, Somi Park, Sunkyung Lee, Bobin Seo, and Sung Min Park Division of Electronic &amp; Semiconductor Engineering, Ewha Womans University</p>
WP-193	<p><b>A Low-Noise CMOS Active-Feedback Transimpedance Amplifier with a Low-Dropout Regulator based on Flipped Voltage Follower</b> Suwon Cho, Sieun Choi, Yiyao Li, Bobin Seo, Somi Park, Sunkyung Lee, Yu Hu, and Sung Min Park Division of Electronic &amp; Semiconductor Engineering, Ewha Womans University</p>
WP-194	<p><b>RF Power Transfer Efficiency Measurement System for Stable Plasma Processing in Semiconductor Manufacturing</b> Narim Lee<sup>1</sup>, Dongjun Min<sup>1</sup>, Hyunjun Kim<sup>1</sup>, Hyunjoo Hwang<sup>2</sup>, Wonwoo Kho<sup>2</sup>, Namjun Kang<sup>3</sup>, and Seung-Eon Ahn<sup>1,2</sup> <sup>1</sup>Department of Nano &amp; Semiconductor Engineering, Tech University of Korea, <sup>2</sup>Department of IT · Semiconductor Convergence Engineering, Tech University of Korea, <sup>3</sup>ion RESEARCH</p>



WP-195	<p><b>Design of a 28-nm FD-SOI Differential Low-Noise Amplifier for 6G Front-End Applications</b></p> <p>Geunwoo Park<sup>1</sup>, Chaeyun Kim<sup>2</sup>, Bohyeon Kim<sup>2</sup>, and Changkun Park<sup>1,2</sup></p> <p><sup>1</sup>School of Electronic Engineering, Soongsil University, <sup>2</sup>Department of Intelligent Semiconductor, Soongsil University</p>
WP-196	<p><b>K-Band CMOS Voltage-Controlled Oscillator for Millimeter-Wave Signal Generation</b></p> <p>Ji-Ho Yoo<sup>1</sup>, Hyeon-Jin Son<sup>2</sup>, and Jong-Ryul Yang<sup>1,2</sup></p> <p><sup>1</sup>Department of Electronics and Electrical Engineering, Konkuk University, <sup>2</sup>Millisight Technologies Co., Ltd.</p>
WP-197	<p><b>First Heterogeneous and Monolithic 3D (HM3D) Integration of InGaAs HEMTs and InP/InGaAs DHBTs on Si CMOS for Next-Generation Wireless Communication</b></p> <p>Nahyun Rheem<sup>1</sup>, Jaeyong Jeong<sup>1</sup>, Yoon-Je Suh<sup>1</sup>, Chan Jik Lee<sup>1</sup>, Bong Ho Kim<sup>1,2</sup>, Joon Pyo Kim<sup>1,2</sup>, Seong Kwang Kim<sup>1,2</sup>, Hyeongrak Lim<sup>1</sup>, Jongmin Kim<sup>3</sup>, Dae-Hwan Ahn<sup>4</sup>, Jae-Hoon Han<sup>4</sup>, Jongwon Lee<sup>5</sup>, and Sanghyeon Kim<sup>1</sup></p> <p><sup>1</sup>School of Electrical Engineering, KAIST, <sup>2</sup>Samsung Electronics Co., Ltd., <sup>3</sup>KANC, <sup>4</sup>Center for Opto-Electronics Materials and Devices, KIST, <sup>5</sup>Department of Semiconductor Convergence, Chungnam National University</p>
WP-198	<p><b>에너지 효율적인 딜레이 라인 기반 LO와 커패시턴스 필스 셰이핑을 이용한 사이드 로브 저감 IR-UWB 송신기</b></p> <p>김민성, 권익진</p> <p>아주대학교 전자공학과</p>
WP-199	<p><b>Modeling Large-Signal RF Behavior Considering Self-Heating and Trap Effects</b></p> <p>Wonwoo Kim<sup>1</sup>, Changho Ra<sup>1</sup>, Dongchan Kim<sup>1</sup>, Jaejoon Woo<sup>2</sup>, and Jonguk Jeon<sup>1</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, Sungkyunkwan University, <sup>2</sup>Department of Semiconductor Convergence Engineering, Sungkyunkwan University</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE1 (4층, 로비)

## [WP] 포스터세션

### T. AI 분과

WP-339	<p><b>Efficient Analog Computing-in-Memory Macro for Block Floating Point Number Format</b></p> <p>Wonkyung Han<sup>1</sup>, Dohyun Kim<sup>1</sup>, Jihoon Park<sup>1</sup>, Juheun Lee<sup>2</sup>, Wonjun Han<sup>2</sup>, and Jae-Joon Kim<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Interdisciplinary Program in Artificial Intelligence, Seoul National University</p>
WP-340	<p><b>Analysis of Group-Wise Quantized Element Distributions Across Different Workloads</b></p> <p>Do Hyun Kim and Jae Joon Kim</p> <p>Department of Electrical and Computer Engineering, Seoul National University</p>
WP-341	<p><b>M<sub>x</sub>FP<sub>4</sub> Dot-Product Engine with Configurable Depth Tree Reduction</b></p> <p>Wonjun Han and Jae-Joon Kim</p> <p>Interdisciplinary Program in Artificial Intelligence, Seoul National University</p>
WP-342	<p><b>A Schmitt-Trigger Comparator-Based Noise-Robust Reconfigurable Leaky Integrate-and-Fire Neuron Circuit for Spiking Neural Networks</b></p> <p>Chae-Hwan Park<sup>1,2</sup>, Seung Yoon Shin<sup>1,2</sup>, Seong Eun Kim<sup>1,2</sup>, Min Kang<sup>1,2</sup>, and Soo-Yeon Lee<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>
WP-343	<p><b>An Efficient LUT-Based FP<sub>16</sub> Exponential Function Approximation for LLM Accelerators</b></p> <p>최성우, 이제훈, 이주찬, 김재준</p> <p>서울대학교 전기·정보공학부</p>



WP-344	<p><b>Random Point Sampling for Faster LiDAR Semantic Segmentation Inference</b> Gyeongseok Hyeon and Injae Yoo School of Electrical and Electronics Engineering, Pusan National University</p>
WP-345	<p><b>Artificial Neuronal Arithmetic based on Ovonic Threshold Switches for Biologically-Inspired Analog Computation</b> Jingyeong Hwang<sup>1,2</sup>, Unhyeon Kang<sup>1,2</sup>, Seungmin Oh<sup>1,3</sup>, Jiin Bang<sup>1,4</sup>, Kyungmin Lee<sup>1,5</sup>, Younghyun Lee<sup>1</sup>, Hakseung Rhee<sup>6</sup>, Jooyoung Bae<sup>1</sup>, and Suyoun Lee<sup>1,4</sup> <sup>1</sup>Center for Semiconductor Technology, KIST, <sup>2</sup>Department of Materials Science and Engineering, Seoul National University, <sup>3</sup>Department of Physics and Astronomy, Seoul National University, <sup>4</sup>Nanoscience and Technology, Korea National University of Science and Technology, <sup>5</sup>Department of Electrical Engineering, Korea University, <sup>6</sup>Department of Materials Science and Engineering, KAIST</p>
WP-346	<p><b>Demonstration of the Hopfield Associative Network Using Cu-Ge<sub>2</sub>Te<sub>1</sub> CBRAM Array</b> Jiin Bang<sup>1,2</sup>, Jingyeong Hwang<sup>2,3</sup>, Unhyeon Kang<sup>2,3</sup>, Seungmin Oh<sup>2,4</sup>, Kyungmin Lee<sup>2,5</sup>, Hakseung Rhee<sup>6</sup>, Younghyun Lee<sup>2</sup>, Jooyoung Bae<sup>2</sup>, and Suyoun Lee<sup>1,2</sup> <sup>1</sup>Nanoscience and Technology, University of Science and Technology, <sup>2</sup>Center for Semiconductor Technology, KIST, <sup>3</sup>Department of Materials Science and Engineering, Seoul National University, <sup>4</sup>Department of Physics and Astronomy, Seoul National University, <sup>5</sup>Department of Electrical Engineering, Korea University, <sup>6</sup>Department of Materials Science and Engineering, KAIST</p>
WP-347	<p><b>ROM 시냅스 기반 면적 최소화형 확률적 SNN</b> 이승준<sup>1,4</sup>, 금건우<sup>1,4</sup>, 김윤<sup>2,4,5</sup>, 구민석<sup>3,4,5</sup> <sup>1</sup>서울시립대학교 지능형반도체학과, <sup>2</sup>서울시립대학교 전자전기컴퓨터공학부, <sup>3</sup>서울시립대학교 첨단융합학부, <sup>4</sup>서울시립대학교 반도체 연구센터, <sup>5</sup>주식회사 IM전자</p>
WP-348	<p><b>듀얼게이트 가우시안 트랜지스터를 이용한 MLP 구현</b> 유영우<sup>1,2</sup>, 조준형<sup>3</sup>, 유희천<sup>4</sup>, 김영준<sup>1,2</sup> <sup>1</sup>가천대학교 반도체공학과, <sup>2</sup>가천대학교 전자공학과, <sup>3</sup>한양대학교 인공지능반도체공학과, <sup>4</sup>한양대학교 융합전자공학과</p>



WP-349	<p><b>Vision Transformer 모델의 최적 토큰 프루닝 레이어 선택을 위한 조건부 계층적 탑색 프레임워크</b> 이승주, 김병수 한국전자기술연구원 SoC플랫폼연구센터</p>
WP-350	<p><b>Performance–Latency Analysis of RAG Systems in On–Device Environments</b> Wonjun Hwang, Seungil Lee, and Hyun Kim Department of Electrical and Information Engineering, Research Center for Electrical and Information Technology, Seoul National University of Science &amp; Technology</p>
WP-351	<p><b>Reinforcement Learning Architecture based on Train–Inference Chains for Resource Optimization</b> Junghwan Choi, Dohyun Kim, and Shiho Kim School of Integrated Technology, BK21 Graduate Program in Intelligent Semiconductor, Yonsei University</p>
WP-352	<p><b>Evaluating Throughput of KV–Cache Offloading Across Memory Tiers</b> Juchan Lee, Hyunjin Kim, Jiwon Song, and Jae–Joon Kim Department of Electrical and Computer Engineering, Seoul National University</p>
WP-353	<p><b>Ternary MAC Architecture with Scaling for Energy–Efficient NPU Design</b> 김도윤, 송다예, 정서현 국민대학교 전자공학부</p>
WP-354	<p><b>A Comparative Analysis of DRAM Architectures for Efficient Test–Time Adaptation in Convolutional Layers</b> Jeongho Kim, Jin Shin, and Hyun Kim Department of Electrical and Information Engineering, Research Center for Electrical and Information Technology, Seoul National University of Science &amp; Technology</p>
WP-355	<p><b>Vertical Si/SiGe/Si Biristor–Based P–Bits for Probabilistic Computing</b> Jaeseoung Park, Jong Pil Im, Hanchan Song, Wangjoo Lee, Jeong Woo Park, and Dongwoo Suh ETRI</p>



WP-356	<p><b>Advancing Semiconductor Reliability through AI and FFT-Enhanced Photo-Induced Current Transient Spectroscopy (PICTS)</b></p> <p>Saegyoung Song<sup>1</sup>, Hui Gu Lee<sup>2</sup>, Byeongchan Sim<sup>1</sup>, Minju Kim<sup>1</sup>, Dong Il Kim<sup>1</sup>, Hyunwee Cho<sup>1</sup>, and Jinpyo Hong<sup>1,2</sup></p> <p><sup>1</sup>Department of Physics, Hanyang University, <sup>2</sup>Division of Nano-scale Semiconductor Engineering and Physics, Hanyang University</p>
WP-357	<p><b>Improving Hardware Efficiency of the Fault Detector for Sliding-Window CNN Accelerator</b></p> <p>Doan Khue Do, Chunmyung Park, Xuan Truong Nguyen, and Hyuk-Jae Lee</p> <p>Department of Electrical and Computer Engineering, Seoul National University</p>
WP-358	<p><b>Lightweight FRC-Aware Mixed Quantization for Robust Edge Speech Recognition</b></p> <p>Hanul Ryu, Minsu Kim, Sungho Lee, and Mingeon Shin</p> <p>KETI</p>
WP-359	<p><b>Hardware Architecture Optimization for Winograd Convolution-Based Edge AI Accelerator</b></p> <p>Minsu Kim, Hanul Ryu, Mingeon Shin, and Sungho Lee</p> <p>Convergence Signal SoC Research Center, KETI</p>
WP-360	<p><b>A Neuromorphic Compute-in-Memory Processor for Efficient Acceleration of SlipReLU-Based ANN-to-SNN Converted Spiking ResNet-18</b></p> <p>Seolhyeon Kim, Suk-Min Yoon, and Min-Seong Choo</p> <p>Department of Electronic Engineering, Hanyang University</p>
WP-361	<p><b>Interface Tuning of HfO<sub>x</sub>/TaO<sub>x</sub> Multilayered Memristor for Implementation of Noise-Aware Neural Network</b></p> <p>Seung Kyu Kang<sup>1</sup>, Sungmin Yu<sup>1,2</sup>, Sang Min Lee<sup>1,3</sup>, Suyoun Lee<sup>1</sup>, Jong-Keuk Park<sup>1</sup>, and Inho Kim<sup>1</sup></p> <p><sup>1</sup>Center for Semiconductor Technology, KIST, <sup>2</sup>Display and Nanosystem Laboratory, School of Electrical Engineering, Korea University, <sup>3</sup>Department of Micro/Nano Systems, Korea University</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE1 (4층, 로비)

## [WP] 포스터세션

### U. Bio-Medical 분과

WP-362	<p><b>Nernst–Planck Model-Based Simulation for Design and Performance Prediction of Iontophoretic Devices</b></p> <p>Jongho Cho<sup>1</sup>, Dongjun Han<sup>2</sup>, Hyemi Lee<sup>3</sup>, Hyungjun Choi<sup>1</sup>, Kyeungbin Kim<sup>1</sup>, and Dong–Wook Park<sup>2</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, University of Seoul, <sup>2</sup>School of Electrical and Computer Engineering, University of Seoul, <sup>3</sup>Department of BioHealth and Eco–Up convergence, University of Seoul</p>
WP-363	<p><b>반도체 공정을 활용한 SERS 바이오 센서 제작</b></p> <p>김수근<sup>1,2</sup>, 강영호<sup>1,3</sup></p> <p><sup>1</sup>전남대학교 물리교육과, <sup>2</sup>전남대학교 광전자융합기술연구소, <sup>3</sup>전남대학교 양자기술연구소</p>
WP-364	<p><b>sEMG 신호의 On-Chip 특징 추출을 위한 VCO-Based Analog Front End 설계</b></p> <p>유희재<sup>1,3</sup>, 구민석<sup>2,3,4</sup>, 김윤<sup>1,3,4</sup></p> <p><sup>1</sup>서울시립대학교 전자전기컴퓨터공학과, <sup>2</sup>서울시립대학교 첨단융합학부, <sup>3</sup>서울시립대학교 반도체연구센터(UOS-FAB), <sup>4</sup>주식회사 IM전자</p>
WP-365	<p><b>Microwave-Processed PZTO Membrane with Plasma-Enhanced Surface Adhesion: From Thin Film to Nanofiber Structure for High-Sensitivity pH</b></p> <p>Seung Jin Lee, Seung-Hwa Choi, and Won-Ju Cho</p> <p>Department of Electronic Materials Engineering, Kwangwoon University</p>
WP-366	<p><b>A Bias-Free and Ultra-Low Interrogation Power RF Biosensor based on Cu-MOF for Dopamine Detection</b></p> <p>Yoongi Cho<sup>1</sup>, Sung moon Park<sup>2</sup>, Seungchan Lee<sup>2</sup>, and Myungsoo Kim<sup>1,2</sup></p> <p><sup>1</sup>Graduate School of Semiconductor Materials and Devices Engineering, UNIST, <sup>2</sup>Department of Electrical and Computer Engineering, UNIST</p>



WP-367	<p><b>MEMS-Fabricated Silicon Nanocolumn CMUT Arrays for Flexible and Disposable Ultrasound Patches</b></p> <p>Seonghun Cho<sup>1,2</sup>, Dong-Hyun Kang<sup>1,3</sup>, Hae Youn Kim<sup>1</sup>, Shinyong Shim<sup>1</sup>, Dong Hun Kim<sup>1</sup>, Baren Jeong<sup>4</sup>, Yoon Seong Lee<sup>4</sup>, Eun-Ah Park<sup>4</sup>, Whal Lee<sup>4</sup>, Hyungmin Kim<sup>1</sup>, Butrus T. Khuri-Yakub<sup>5</sup>, Maesoon Im<sup>6,7,8</sup>, Jae-Woong Jeong<sup>2</sup>, and Byung Chul Lee<sup>1,7,8</sup></p> <p><sup>1</sup>Bionics Research Center, KIST, <sup>2</sup>School of Electrical Engineering, KAIST, <sup>3</sup>Department of Mechanical Engineering, Gangneung-Wonju National University, <sup>4</sup>Department of Radiology, Seoul National University Hospital, <sup>5</sup>Department of Electrical Engineering, Stanford University, <sup>6</sup>Brain Science Institute, KIST, <sup>7</sup>Division of Bio-Medical Science and Technology, KIST School, University of Science and Technology, <sup>8</sup>KHU-KIST Department of Converging Science and Technology, Kyung Hee University</p> <p><b>췌장암 치료를 위한 3차원 자가적응, 삽입형 마이크로 LED 소자Self-Adaptive, Three-Dimensional Implantable MicroLEDs for Pancreatic Cancer Therapy</b></p> <p>Minseo Kim, Jae Hee Lee, and Keon Jae Lee</p> <p>Department of Materials Science and Engineering, KAIST</p> <p><b>G-ISFET 의 Dirac Point 산포를 줄이기 위한 인터페이스 회로 IP</b></p> <p>Sohyeon Ahn, Kwang Soup Song, and Ji-Yong Um</p> <p>Department of Medical IT Convergence Engineering, Kumoh National Institute of Technology</p>
--------	--



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE2-1 (5층, 로비)

## [WP] 포스터세션

### Q. Metrology, Inspection, Analysis, and Yield Enhancement 분과

WP-220	초고속 상관 화학기계연마 계측을 위한 위상 이동 간섭계와 능동 탐침 주사 탐침 현미 경 통합 기술 유준호, 장재영 넥센서
WP-221	반도체 생산라인의 Optical Inspection 장비에서 Beam Alignment 동작 분석 기반 의 생산성 향상 및 산포 저감 전략 신효섭 <sup>1,2,3</sup> , 신동균 <sup>4</sup> <sup>1</sup> 성균관대학교 반도체디스플레이공학과, <sup>2</sup> 삼성전자 메모리사업부, <sup>3</sup> Samsung Advanced Institute of Technology, <sup>4</sup> 성균관대학교 소프트웨어 컴퓨터 공학과
WP-222	Rapid Analysis of SiGe Composition by Wide-Field Raman Spectroscopy Chanwoo Kim and Hyuksang Kwon KRISS
WP-223	차세대 3D 반도체 공정을 위한 오토인코더 기반 오버레이 계측 정밀도 향상 기법 이현철 <sup>1,3</sup> , 장현진 <sup>1</sup> , 우호성 <sup>2</sup> , 이원규 <sup>3</sup> <sup>1</sup> 오로스테크놀로지, <sup>2</sup> 한국방송통신대학교, <sup>3</sup> 고려대학교
WP-224	Development of a Z-Pinch Plasma Source-Based Testing Platform for Optical Characterization of Materials Used in Extreme Ultraviolet Lithography Eun-Seok Choe <sup>1,2</sup> , Wooram Kim <sup>1</sup> , Do-Yeon Hwang <sup>1,4</sup> , Hee-Jung Yeom <sup>1</sup> , Jinhoo Seong <sup>1,4</sup> , Gwang-Seok Chae <sup>1,4</sup> , Young-Gi Kim <sup>3</sup> , Hyo-Chang Lee <sup>4</sup> , Hyun-Dam Jeong <sup>5</sup> , Won Chegal <sup>1,6</sup> , Dong-Wook Kim <sup>2</sup> , and Jung-Hyung Kim <sup>1</sup> <sup>1</sup> Semiconductor and Display Metrology Group, KRISS, <sup>2</sup> Department of Radio and Information Communications Engineering, Chungnam National University, <sup>3</sup> Korea Institute of Fusion Energy, <sup>4</sup> Department of Semiconductor Science, Engineering and Technology, Korea Aerospace University, <sup>5</sup> Department of Chemistry, Chonnam National University, <sup>6</sup> Graduate School of Analytical Science and Technology, Chungnam National University



WP-225	<p><b>Development of an Extreme Ultraviolet Light Source via Dual-Pulse Laser-Produced Plasma for EUV Lithography Material Evaluation Systems</b></p> <p>Do-Yeon Hwang<sup>1,2</sup>, Wooram Kim<sup>1</sup>, Eun-Seok Choe<sup>1</sup>, Chegal Won<sup>1</sup>, Young-Gi Kim<sup>3</sup>, Hyo-Chang Lee<sup>2,4</sup>, and Jung-Hyung Kim<sup>1</sup></p> <p><sup>1</sup>KRISS, <sup>2</sup>Department of Semiconductor Science, Engineering and Technology, Korea Aerospace University, <sup>3</sup>Korea Institute of Fusion Energy, <sup>4</sup>School of Electronics and Information Engineering, Korea Aerospace University</p>
WP-226	<p><b>절연체 기반 유전영동을 이용한 반도체 공정용 학물질 내 나노입자 정제 기술</b></p> <p>이승윤<sup>1</sup>, 장진혁<sup>2</sup>, 오준영<sup>2</sup>, 김영훈<sup>2</sup>, 최삼종<sup>2</sup>, 김윤호<sup>2</sup>, 김지현<sup>1</sup></p> <p><sup>1</sup>서울대학교 화학생물공학부, <sup>2</sup>삼성전자 소재기술팀</p>
WP-227	<p><b>Quantitative Hydrogen Analysis by Time of Flight-Elastic Recoil Detection Analysis (TOF-ERDA) Using Medium Energy Ion</b></p> <p>Kyungsu Park, Jwa Soon Kim, Jiho Song, Haejoon Hahm, Soobang Kim, Jong Hun Kim, and Won Ja Min</p> <p>HB Solution Co., Ltd.</p>
WP-228	<p><b>광섬유 전단력 현미경 기반 초고분해능 열영상 이미징 기술</b></p> <p>정문경, 김동욱, 정찬배, 김동목, 장기수</p> <p>한국기초과학지원연구원 연구장비개발부</p>
WP-229	<p><b>Electrical Property Enhancement in MOCVD-Grown MoS<sub>2</sub> FETs: Comparative Insights into Contact Strategies</b></p> <p>Junghyun Lee<sup>1,2</sup>, Sanghwa Lee<sup>1,2</sup>, Hyunwoo Kim<sup>1,2</sup>, Bongjoong Kim<sup>2</sup>, and Jun Oh Kim<sup>2</sup></p> <p><sup>1</sup>KRISS, <sup>2</sup>Hongik University</p>
WP-230	<p><b>Design and Optimization of Quasi-3D Hole Array Nanostructures for High-Efficiency Plasmonic Filters</b></p> <p>Tae-kyung Im<sup>1,2</sup>, Jehwan Hwang<sup>3</sup>, Hyunwoo Kim<sup>1,2</sup>, Sanghwa Lee<sup>1,2</sup>, Bongjoong Kim<sup>2</sup>, and Jun Oh Kim<sup>1</sup></p> <p><sup>1</sup>KRISS, <sup>2</sup>Mechanical Engineering, Hongik University, <sup>3</sup>Optical Lens Materials Research Center, KOPTI</p>



WP-231	<p><b>Comparative Study of Channel Geometry and Electrical Performance in MoS<sub>2</sub> FETs</b></p> <p>Hyunwoo Kim<sup>1,2</sup>, Do Kyung Kim<sup>3</sup>, Junghyun Lee<sup>1,2</sup>, Sangwha Lee<sup>1,2</sup>, Bongjoong Kim<sup>2</sup>, and Jun Oh Kim<sup>1</sup></p> <p><sup>1</sup>KRISS, <sup>2</sup>Hongik University, <sup>3</sup>Kangwon National University</p>
WP-232	<p><b>E-Beam Generated Fast-Traps in MoS<sub>2</sub> Transistors through Transient I-V Characterization</b></p> <p>Joonyup Bae<sup>1</sup>, Sunghan Cho<sup>1,2</sup>, Nagyeong Lee<sup>1</sup>, and Jihyun Kim<sup>1</sup></p> <p><sup>1</sup>Department of Chemical and Biological Engineering, Seoul National University, <sup>2</sup>Global Manufacturing and Infra Technology, Samsung Electronics Co., Ltd.</p>
WP-233	<p><b>Thermal Property Imaging for 3D Packaging Using Frequency-Domain Thermoreflectance</b></p> <p>Dongyun Seo, Jihyun Kim, Kyusung Han, and Jungwan Cho</p> <p>School of Mechanical Engineering, Sungkyunkwan University</p>
WP-234	<p><b>Diffraction Diversity 향상을 통한 EUV Ptychography 이미지 복원 성능 개선 연구</b></p> <p>홍준호<sup>1,3</sup>, 문승찬<sup>2,3</sup>, 이태호<sup>3</sup>, 안진호<sup>1,2,3</sup></p> <p><sup>1</sup>한양대학교 신소재공학과, <sup>2</sup>한양대학교 나노반도체공학과, <sup>3</sup>극한스케일·극한물성-이종 집적 한계극복 반도체 기술 연구센터</p>
WP-235	<p><b>4D-STEM과 EELS을 이용한 Hf<sub>0.5</sub>Zr<sub>0.5</sub>O<sub>2</sub> 강유전상에서의 산소공공 분포와 상안정화 상관성 분석</b></p> <p>성민찬<sup>1</sup>, 정지훈<sup>1</sup>, 이기용<sup>1</sup>, 박범수<sup>2</sup>, 이성호<sup>1</sup>, 정지원<sup>1</sup>, 오상호<sup>1</sup></p> <p><sup>1</sup>한국에너지공과대학교 에너지공학부, <sup>2</sup>삼성전자 반도체연구소</p>
WP-236	<p><b>Micron-Scale Thermal Property Characterization Using Thermo-Optic Phase Spectroscopy (TOPS)</b></p> <p>Kyusung Han, Jihyun Kim, Taeyeon Kim, Dongyun Seo, and Jungwan Cho</p> <p>School of Mechanical Engineering, Sungkyunkwan University</p>
WP-237	<p><b>Non-Destructive Material Characterization Using a Compact Multispectral LWIR Imaging Module</b></p> <p>Jejung Lee<sup>1</sup>, Yonghun Cho<sup>1</sup>, Danwon Lee<sup>1</sup>, Gimin Bae<sup>2</sup>, and Young Hwa Lee<sup>1</sup></p> <p><sup>1</sup>Next-Generation C5 System Department, Institute of Innovation for Future Army, <sup>2</sup>DDOK, Co. Ltd.</p>



WP-238	<p><b>Quantitative Evaluation of Probe Current Stability in Scanning Electron Microscopes for Semiconductor Metrology</b></p> <p>Ha Rim Lee<sup>1</sup>, Youngkwon Haam<sup>1,3</sup>, Junhyeok Hwang<sup>1</sup>, Jeong-Woong Lee<sup>1</sup>, Haewon Jung<sup>1</sup>, Hoon Kang<sup>1</sup>, Junhyeong Park<sup>1</sup>, Hyunmo Gu<sup>1</sup>, Insu Seo<sup>1</sup>, and In-Yong Park<sup>1,2,3</sup></p> <p><sup>1</sup>Strategic Technology Research Institute, KRISS, <sup>2</sup>Major in Nanoconvergence Measurement, University of Science and Technology, <sup>3</sup>Graduate School of Analytical Science and Technology, Chungnam National University</p>
WP-239	<p><b>Voltage Contrast Inspection of an Electrical Defect on a Semiconductor Wafer with X-Ray Photoelectron Spectroscopy and an Electron Beam</b></p> <p>Gyungtae Kim<sup>1</sup>, Tae Gun Kim<sup>1</sup>, Chil-sung Jung<sup>1</sup>, Yunju Oh<sup>1</sup>, and Bongjin Simon Mun<sup>2</sup></p> <p><sup>1</sup>NNFC, <sup>2</sup>GIST</p>
WP-240	<p><b>Artificial Neural Network-Based Detection of In-Cell Region Pattern Non-Uniformity</b></p> <p>ChangHwan Lee, SeuRi Jeong, and DkNyon Lee</p> <p>SK hynix Inc.</p>
WP-241	<p><b>Metrology and Inspection을 위한 SEM 이미지 복원 및 응용</b></p> <p>황준혁, 이정웅, 박인용, 오가와 타카시</p> <p>한국표준과학연구원 미래선도연구장비그룹</p>
WP-242	<p><b>Johnsen-Rahbek형 정전척의 표면 형상에 따른 Chucking Mechanism 고찰</b></p> <p>김범수, 조지훈, 김창훈</p> <p>(주)보부하이테크</p>
WP-243	<p><b>3D 구조 하부 결합 분석을 위한 In-Line 파괴 검사 기법 개발</b></p> <p>Do Young Choi, Jae Cheol Jo, and Kyu Young Kim</p> <p>SK Hynix Inc.</p>
WP-244	<p><b>Effect of Sulfur Passivation on the Electrical Characteristics of InGaAs-InP Heterojunction TFET</b></p> <p>Jong Hwan Park, Min Su Kim, Dong Hwi Choi, Jae Hyeop Lee, and Jae Cheol Shin</p>



# 제 33회 한국반도체학술대회

The 33rd Korean Conference on Semiconductors

2026년 1월 27일(화)-30일(금) | 강원도 하이원리조트 그랜드호텔(컨벤션타워)

A Paradigm Shift in Semiconductors for AI Era

---

Department of Electronics and Electrical Engineering, Dongguk University

---



WP-245	<p><b>Enhancing Yield and Variability Control of 8-Inch CMOS-Compatible RRAM for Mass Production Applications</b></p> <p>Heesoo Yang, Woo-Seok Kim, Bonseong Gu, Youna Kwon, Sanghwa Lee, Won-chul Lee, Dong-wook Lee, Seung Jong Yoo, Gap Sup Sim, Young Joo Kim, Woo-Suk Sul, and Kanghyeok Jeon</p> <p>NNFC</p>
WP-246	<p><b>Fabrication of a Laser-Integrated TEM Holder and Drift Benchmarking toward In-Situ Micro Solder Bump</b></p> <p>Yun Jae Jung, Hui Won Park, Ye Rim Kang, Hyun Jin Choi, Jin Young Kim, and Young Heon Kim</p> <p>Department of Analytical Science and Technology, Graduate School of Analytical Science and Technology, Chungnam National University</p>
WP-247	<p><b>Analysis of EUV Light Source based on the Cold Cathode Electron Beam Irradiation with Multilayer Mirror Measurement for Actinic Inspection Technique</b></p> <p>Iksu Kim, Umesh Balaso Apugade, Dana Chung, and Kyu Chang Park</p> <p>Department of Information Display, Kyung Hee University</p>
WP-248	<p><b>Development and Assessment of an Air-Free Transfer Holder for Reliable TEM Characterization of Air-Sensitive Semiconductors</b></p> <p>Hui Won Park, Yun Jae Jung, and Young Heon Kim</p> <p>Graduate School of Analytical Science and Technology, Chungnam National University</p>
WP-249	<p><b>Microstructural Property and Formation Mechanism of Cracks in AlInN/GaN Heterostructure</b></p> <p>Chan Hee Hwang<sup>1</sup>, Da Mi Kwon<sup>1</sup>, Hyeon Jin Choi<sup>1</sup>, Jong Hoon Kim<sup>1</sup>, Eun Ah Cheon<sup>2</sup>, Young Kyun Noh<sup>2</sup>, and Young Heon Kim<sup>1</sup></p> <p><sup>1</sup>Graduate School of Analytical Science and Technology, Chungnam National University, <sup>2</sup>IVWorks Co., Ltd.</p>
WP-250	<p><b>Pellicle Inspection Technique based on the EUV Light Source with Cold Cathode Electron Beam</b></p> <p>Umesh Balaso Apugade, Iksu Kim, and Kyu Chang Park</p> <p>Department of Information Display, Kyung Hee University</p>
WP-251	<p><b>Fabrication and Reliable Evaluation of MEMS Heating Chips for In-Situ TEM</b></p>



	<p>Ji Min Lee<sup>1</sup>, Jin Young Kim<sup>1</sup>, Dae Yeon Kim<sup>1</sup>, Yun Jae Jung<sup>1</sup>, Hui Won Park<sup>1</sup>, Hoil Cha<sup>2</sup>, Jong Cheol Park<sup>2</sup>, Yun Chang Park<sup>2</sup>, and Young Heon Kim<sup>1</sup> <sup>1</sup>Department of Analytical Science and Technology, Graduate School of Analytical Science and Technology, Chungnam National University, <sup>2</sup>NNFC</p>
WP-252	<p><b>Optical and Electronic Responses of 2D van der Waals Heterostructures Probed by Temperature-Dependent Infrared Ellipsometry</b> Sukhyun Choi, Yongjai Cho, Junghoon Yang, Jongkyoon Park, and Won Chegal Semiconductor and Display Metrology Group, KRISS</p>
WP-253	<p><b>플라즈마 식각 환경에서 이트륨계 소재의 오염입자 발생 실시간 분석 연구</b> 이래원<sup>1,3</sup>, 민병현<sup>1,2</sup>, 강상우<sup>1,2</sup>, 김태성<sup>3</sup>, 문지훈<sup>1</sup> <sup>1</sup>한국표준과학연구원 전략기술연구소, <sup>2</sup>과학기술연합대학교대학원 정밀측정, <sup>3</sup>성균관대 학교 성균나노과학기술원</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE2-1 (5층, 로비)

## [WP] 포스터세션

### S. Chip Design Contest 분과

WP-254	<p><b>A Half-VDD Biased Capacitively Driven On-Chip Link With Switched-Capacitor Signaling</b></p> <p>Wonbin Lee<sup>1</sup>, Soonwon Kwon<sup>2</sup>, In-Woo Jang<sup>1</sup>, Jae-Seung Jeong<sup>1,3</sup>, Sara Kim<sup>1</sup>, and Kyeongha Kwon<sup>1</sup></p> <p><sup>1</sup>KAIST, <sup>2</sup>MediaTek, <sup>3</sup>Samsung Electronics Co., Ltd</p>
WP-255	<p><b>An 850<math>\mu</math>W, 2-to-5GHz Jitter-Filtering and Instant-Toggling Injection-Locked Quadrature-Clock Generator for Low-Power Clock Distribution in HBM Interfaces</b></p> <p>Jeongbeom Seo<sup>1</sup>, Yuhwan Shin<sup>2</sup>, and Jaehyouk Choi<sup>1</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Electrical Engineering, KAIST</p>
WP-256	<p><b>A 0.4-VDDQ 11.5-Gb/s/pin Transmitter with Switched-Coupling Charge-Pump Crosstalk Cancellation Achieving Eye-Margin Recovery for Ultra-Dense Die-to-Die Interfaces</b></p> <p>Yoochang Kim<sup>1</sup> and Young-Ha Hwang<sup>1,2</sup></p> <p><sup>1</sup>Department of Intelligent Semiconductors, Soongsil University, <sup>2</sup>School of Electronic Engineering, Soongsil University</p>
WP-257	<p><b>A Low-Power 8-b 500MS/s Three-Comparator SAR ADC with Background Comparator-Swapping Offset Calibration</b></p> <p>Seunghyun Kim and Minjae Lee</p> <p>School of Electrical Engineering and Computer Science, GIST</p>
WP-258	<p><b>A Temperature-Compensated LDO with Embedded Voltage Reference for Compact SoCs in 65nm CMOS</b></p> <p>Beomsoo Kim<sup>1</sup>, Yuli han<sup>2</sup>, and Kunhee Cho<sup>1</sup></p> <p><sup>1</sup>Department of Semiconductor Convergence Engineering, Sungkyunkwan University, <sup>2</sup>DB Global Chip</p>



WP-259	<p><b>Small-Area, High-Speed, and High Uniformity Source Driver IC for OLED-on-Silicon (OLEDoS) Displays</b></p> <p>Jung Hwan Oh, Wi Man Yoo, Dong Kun Lee, and Jong Seok Kim</p> <p>Department of Electronics and Electrical Engineering, Hanyang University ERICA</p>
WP-260	<p><b>A High-Efficiency Low-Ripple Pulse-Frequency Modulation Buck Converter for Light-Load Applications</b></p> <p>Gang-Bae Park, So-Hyun Lee, Hye-Seon Choi, and Jong-Seok Kim</p> <p>Department of Electrical and Electronic Engineering, Hanyang University ERICA</p>
WP-261	<p><b>In-Memory-Computing Architecture for Closed-Loop Peripheral Nerve Modulation Implants</b></p> <p>Donghyeon Yi<sup>1</sup>, Seoyoung Lee<sup>2</sup>, and Minkyu Je<sup>1</sup></p> <p><sup>1</sup>School of and Electrical Engineering, KAIST, <sup>2</sup>IMEC</p>
WP-262	<p><b>An Energy-Efficient Multi-Cell Battery Charger with Simultaneous Charging and Balancing</b></p> <p>Seongil Yeo and Kunhee Cho</p> <p>Department of Semiconductor Convergence Engineering, Sungkyunkwan University</p>
WP-263	<p><b>Second-Order Feedforward <math>\Delta \Sigma</math> Converter for High-Sampling-Rate Current-Type Bio Signal Measurement</b></p> <p>Minseok Park and Chul Kim</p> <p>Department of Bio and Brain Engineering, KAIST</p>
WP-264	<p><b>A 100-Mb/s TIA-first Galvanic-Coupling Communication Receiver for Neural Implant Systems</b></p> <p>이현엽, 이동윤, 정윤철, 제민규</p> <p>한국과학기술원 전기 및 전자공학부</p>
WP-265	<p><b>A Design Technique for Highly Parallel PRTS Generators</b></p> <p>Jusung Park and Jintae Kim</p> <p>Konkuk University</p>
WP-266	<p><b>Single-Photon Avalanche Diode Based X-Ray Detector</b></p> <p>Hyun-Seung Choi and Youngcheol Chae</p> <p>Yonsei University</p>



WP-267	<p><b>A Design Technique for Linearity Enhanced Dynamic Amplifier</b> Gwangmin Jung and Jintae Kim Konkuk University</p>
WP-268	<p><b>An Energy-Efficient Keyword Spotting Processor with Zero-Aware Feature Skipping and Relaxed Convolution</b> Sangyeon Kim<sup>1</sup>, Seongmin Ki<sup>1</sup>, and Sungju Ryu<sup>2</sup> <sup>1</sup>Department of Electronic Engineering, Sogang University, <sup>2</sup>Department of System Semiconductor Engineering, Sogang University</p>

WP-269	<p><b>A Single-Ended PAM-3 Transmitter with Multiplexing Driver for Memory Interfaces</b> Chan-Hee Jeon and Yong-Un Jeong School of Semiconductor Systems Engineering, Sejong University</p>
WP-270	<p><b>A 9.4-fs-FoM Fast Transient Switched-Capacitor LDO in 28-nm CMOS</b> Sangwoong Sim, Donghwan Kim, and Jaehoon Jun Departmentl of Electrical and Computer Engineering, Inha University</p>
WP-271	<p><b>Mutual Locking of Buffered Oscillators via Inter-Core Line</b> 김준성, 김문일 고려대학교 초고주파 연구실</p>
WP-272	<p><b>A V-Band Vector Sum Phase Shifter over a Wide Band Width in 28nm CMOS Technology</b> Hyeong Jin An and Chul Woo Byeon <sup>1</sup>Department of Electronic and Electrical Engineering, Dankook University</p>
WP-273	<p><b>A V-band Power Divider/Combiner with a Tunable Isolation Band Using a Capacitor Bank in 28nm CMOS Technology</b> Yeon Soo Lim and Chul Woo Byeon Department of Electronic and Electrical Engineering, Dankook University</p>
WP-274	<p><b>A V-Band 2-Stage Low-Phase-Error Variable Gain Amplifier with 0.5dB Resolution of 24dB Gain Range in 65nm CMOS Technology</b> In Cheol Yoo and Chul Woo Byeon Department of Electronic and Electrical Engineering, Dankook University</p>



# 제 33회 한국반도체학술대회

The 33rd Korean Conference on Semiconductors

2026년 1월 27일(화)-30일(금) | 강원도 하이원리조트 그랜드호텔(컨벤션타워)

A Paradigm Shift in Semiconductors for AI Era



WP-275	<p><b>Time-Interleaved Nyquist and Delta-Sigma Current-Steering DACs for Wireless Transmitter</b></p> <p>Hyunyoung Yoo<sup>1</sup>, Yeonsu Kim<sup>1</sup>, Su-Hyeon Kim<sup>1</sup>, Eunji Yoo<sup>1</sup>, Gu-Hyeon Lee<sup>1</sup>, Jae-Yun Park<sup>2</sup>, and Jae-Won Nam<sup>1</sup></p> <p><sup>1</sup>Department of Electronic Engineering, Seoul National University of Science &amp; Technology, <sup>2</sup>Agency for Defense Development</p>
WP-276	<p><b>Design of Analog Front-End for the Wideband Wireline Receiver</b></p> <p>Hyunyoung Yoo<sup>1</sup>, Su-Hyeon Kim<sup>1</sup>, Yeonsu Kim<sup>1</sup>, Eunji Yoo<sup>1</sup>, Gu-Hyeon Lee<sup>1</sup>, Jae-Yun Park<sup>2</sup>, and Jae-Won Nam<sup>1</sup></p> <p><sup>1</sup>Department of Electronic Engineering, Seoul National University of Science &amp; Technology, <sup>2</sup>Agency for Defense Development</p>
WP-277	<p><b>Gate- and Body-Driven OLEDoS Pixel Circuit for a Wide Data Range</b></p> <p>Chanjin Park and Soo-Yeon Lee</p> <p>Department of Electrical and Computer Engineering, Seoul National University</p>
WP-278	<p><b>Energy-Efficient Compression Architecture for Molecular Dynamics</b></p> <p>Seongmin Ki, Sangyeon Kim, and Sungju Ryu</p> <p>Sogang University</p>
WP-279	<p><b>A Low-Dropout Regulator Using Gain-Boosting OTA and Dynamic Feedback Compensation for Low Power DRAM Cores</b></p> <p>Min Cheol Kim, Ju Hong Min, and Jang Hyun Kim</p> <p>Department of Intelligence Semiconductor Engineering, Ajou University</p>
WP-280	<p><b>Scalable Neuromorphic Architecture with STDP based on Chip Learning for Edge Devices</b></p> <p>SuHwan Na, SungHyun Cha, and DongSun Kim</p> <p>Department of Semiconductor Systems Engineering, Sejong University</p>
WP-281	<p><b>A 5V-Input 0.6-to-2.2V Output 3 Level Step-Down Converter Using Open Loop Based Flying Capacitor Voltage Balancing for DDR5 VRoD PMICs</b></p> <p>최정진<sup>1</sup>, 이정섭<sup>2</sup>, 윤제훈<sup>1</sup>, 유승완<sup>1</sup>, 최우석<sup>1</sup>, 이강윤<sup>1</sup></p> <p><sup>1</sup>성균관대학교 전자전기컴퓨터공학과, <sup>2</sup>성균관대학교 반도체디스플레이공학과</p>
WP-282	<p><b>A 90GHz Passive Mixer-First Receiver in 28-nm CMOS</b></p> <p>최규빈, 노승모, 최우열</p> <p>서울대학교 전기정보공학부</p>



WP-283	<p><b>12-Bit High Resolution-Area Efficient Current DAC</b></p> <p>Dong Hun Cha<sup>1</sup>, Ji Seong Kim<sup>2</sup>, Se Woong Jeong<sup>1</sup>, Yu Jin Lee<sup>1</sup>, and Jeong Hoan Park<sup>1,2</sup></p> <p><sup>1</sup>Department of Semiconductor Engineering, Kyung Hee University, <sup>2</sup>Department of Electronic Engineering, Kyung Hee University</p>
WP-284	<p><b>Reconfigurable Regulating Rectifier with Minimized Conduction and Switching Loss in 130nm BCDMOS</b></p> <p>신도현, 흥진우, 허준영, 김지민, 김종민, 범진욱</p> <p>Department of Electronic Engineering, Sogang University</p>
WP-285	<p><b>High-Speed and Highly Reliable 3-T Embedded NOR Flash Memory for Standard CMOS Process</b></p> <p>Min Se Kim<sup>1,2</sup>, Jae Seung Woo<sup>1,2</sup>, and Woo Young Choi<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>
WP-286	<p><b>Biopotential Amplifier with SNR-Optimizing Technique under Harsh Contact Impedance Conditions</b></p> <p>Younghun Jeong and Nhamil Koo</p> <p>School of Foundry Engineering, Dankook University</p>
WP-287	<p><b>Compact Integration of RDAC and High-Pass Filter for Battery Electrochemical Impedance Spectroscopy</b></p> <p>ByeongHo Hwang<sup>1</sup>, UiKyoung Lee<sup>1</sup>, JiHan Shin<sup>2</sup>, and KyeongHa Kwon<sup>1,2</sup></p> <p><sup>1</sup>School of Electrical Engineering, KAIST, <sup>2</sup>Graduate School of AI Semiconductor, KAIST</p>
WP-288	<p><b>Energy-Efficient Ternary Content-Addressable Memory based on One Capacitor and One Nanoelectromechanical Memory Switch Memory Cell</b></p> <p>Myeong Su Shin<sup>1,2</sup>, Geun Tae Park<sup>1,2</sup>, Jin Wook Lee<sup>1,2</sup>, and Woo Young Choi<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>



WP-289	<p><b>Nanoelectromechanical Physically Unclonable Function for Resource-Constrained IoT Environments</b></p> <p>Seung Hun Baek<sup>1,2</sup>, Jin Wook Lee<sup>1,2</sup>, Geun Tae Park<sup>1,2</sup>, and Woo Young Choi<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>
WP-290	<p><b>Low-Power Analog CMOS Neuron Circuits for Solving Fan-in Issues in Spiking Neural Network Systems</b></p> <p>Seongjin Kim<sup>1,2,3</sup>, Jonghyuk Park<sup>1,2</sup>, Yeonwoo Kim<sup>1,2</sup>, and Woo Young Choi<sup>1,2</sup></p> <p><sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University, <sup>3</sup>Flash Design Team, Samsung Electronics Co., Ltd.</p>
WP-291	<p><b>A 20 GHz Integer-N PLL with Injection-Locked Frequency Divider-by-4 in 28 nm CMOS</b></p> <p>Young Jun Byun, Min Gi Seo, and Gyungsu Byun</p> <p>Department of Electrical and Computer Engineering, Inha University</p>
WP-292	<p><b>A Low-Power CMOS Non-Linear DDS for Non-Faradaic EIS Biosensors</b></p> <p>Jun-Seok Beom, Kang-Woo Choi, and Nam-Seog Kim</p> <p>School of Information and Communication Engineering, Chungbuk National University</p>
WP-293	<p><b>Design of Polysilicon Grating Couplers Using Metal Reflector in FD-SOI Platform</b></p> <p>Jiwi Park, Chaewon Jeon, and Kyoungsik Yu</p> <p>KAIST</p>
WP-294	<p><b>A High-Voltage Double Step-Down Converter with Perturb &amp; Observe MPPT Technique in Solar PV System</b></p> <p>Tae-Ryeong Kim and Jong-Wook Lee</p> <p>Department of Electronic Engineering, Kyung Hee University</p>
WP-295	<p><b>Micro-Bolometer Thermal Imager with Ambient Temperature Compensated Sensor Sensitivity</b></p> <p>Jongho Jung, Taehyung Kim, Kiwon Seo, and Gunhee Han</p> <p>School of Integrated Technology, Yonsei University</p>



WP-296	<p><b>Design of W-band Power Amplifier and Low-Noise Amplifier for High-Speed Dielectric Waveguide Link</b></p> <p>이영한, 이성준, 최우열 서울대학교 전기정보공학부</p>
WP-297	<p><b>A Dual Supply-Ground Voltage Regulation Scheme Using Low-Dropout Regulators for CMOS SoCs</b></p> <p>Hee-Cheol Joo<sup>1</sup> and Young-Ha Hwang<sup>1,2</sup></p> <p><sup>1</sup>Department of Intelligent Semiconductors, Soongsil University, <sup>2</sup>School of Electronic Engineering, Soongsil University</p>
WP-298	<p><b>Differential Sense Amplifier Integrating Precharge and Offset Compensation Process</b></p> <p>Chaebin Kim<sup>1</sup> and Keewon Kwon<sup>2</sup></p> <p><sup>1</sup>Department of Electronic and Electrical Engineering, Sungkyunkwan University, <sup>2</sup>Department of Semiconductor System Engineering, Sungkyunkwan University</p>
WP-299	<p><b>HVLS-Based Cell-Selective EIS Structure for Series-Connected Multi-Cells</b></p> <p>Ayeon Gwon, Yeseul Song, and Junwon Jeong Sookmyung Women's University</p>
WP-300	<p><b>DC-DC Converter with Pulse-Skip Mode for Low-Power Operation</b></p> <p>Minseok Kim, Haechan Park, Jiho Jung, Minkwang Ji, Jooyun Oh, Sungwan Hong, Jihun Oh, Heejun Byeon, Huiseung Chae, Jaehyeok Lee, Kyungseok Lee, and Joongho Choi University of Seoul</p>
WP-301	<p><b>A Second-Order Noise-Shaping SAR ADC with 3-Level-Switching CDACs Employing a Novel DWA</b></p> <p>김준형, 나우성, 조장현, 최보성, 고경보, 권준석, 박상규 한양대학교 응집전자공학과</p>
WP-302	<p><b>A K-Band Doherty Power Amplifier with Transformer-Based Matching Network for 6G and Beyond Wireless Communication</b></p> <p>이성준, 김준엽, 최우열 서울대학교 전기정보공학부</p>



WP-303	<p><b>An Error Correcting Code Encoder Utilizing Orthogonal Latin Square Code for HBM Application</b></p> <p>Yue Ri Jeong, Sangho Lee, Seongmo An, Jinyeol Kim, and Seung Eun Lee Department of Electronic Engineering, Seoul National University of Science &amp; Technology</p>
WP-304	<p><b>Gray Code Counter-Based Loopback Verification Framework for RCD Control Word Functionality in 28nm CMOS</b></p> <p>Saransh Rajjarwal, Min-Gi Seo, Young-Jun Byun, and Gyung Su Byun Department of Electrical and Computer Engineering, Inha University</p>
WP-305	<p><b>Input Bus Termination Calibration with Digital Controller Design for High-Speed Memory Interface</b></p> <p>Saransh Rajjarwal, Min-Gi Seo, Young-Jun Byun, and Gyung Su Byun Department of Electrical and Computer Engineering, Inha University</p>
WP-306	<p><b>8-Way FDM-Based 500 MHz BW DDFS for a Baseband Qubit Controller</b></p> <p>Hyunyoung Yoo<sup>1</sup>, Su-Hyeon Kim<sup>1</sup>, Muhammad Fakhri Mauludin<sup>2</sup>, Yeonsu Kim<sup>1</sup>, Eunji Yoo<sup>1</sup>, Gu-Hyeon Lee<sup>1</sup>, Jae-Yun Park<sup>3</sup>, Jusung Kim<sup>4</sup>, and Jae-Won Nam<sup>1</sup></p> <p><sup>1</sup>Department of Electronic Engineering, Seoul National University of Science &amp; Technology, <sup>2</sup>Department of Electronics Engineering, Hanbat National University, <sup>3</sup>Agency for Defense Development, <sup>4</sup>Division of Electronic and Semiconductor Engineering, Ewha Womans University</p>
WP-307	<p><b>가변 부하 배터리 밸런싱을 위한 High-VDS, Low-<math>r_{on}</math> Stacked CMOS Switch IC</b></p> <p>이규환, 최동국, 최수로, 김상혁, 이경태 Department of Electrical Engineering and Computer Science, DGIST</p>
WP-308	<p><b>A Sub-1-V Bandgap Reference Circuit with High PSRR</b></p> <p>Minoo Lee, Gahyeon Sung, and Junghyup Lee DGIST</p>
WP-309	<p><b>Low-Power Wideband 4.8–7.2 GHz Balun-LNA with Local Feedback gm-Boosting and Current-Bleeding for Wi-Fi 7 Applications</b></p> <p>Youngchae Lee, Chaerin Park, and Kuduck Kwon Department of Electronic Engineering, Kangwon National University</p>



WP-310	<p><b>A Blocker-Tolerant Balun-LNTA with Integrated Dual-Band LC Notch Filter for Sub-6 GHz 5G NR Receivers</b> Sejin Lee, Seungyeon Kim, and Kuduck Kwon Department of Electronic Engineering, Kangwon National University</p>
WP-311	<p><b>A Dual-Band N-Path Balun-LNA for 5G New Radio Cellular Applications</b> Byounghyun You, Heesu Lee, and Kuduck Kwon Department of Electronic Engineering, Kangwon National University</p>
WP-312	<p><b>A Pipelined ADC With a Gain-Boosted Dynamic Amplifier</b> Bo Gao, Raymond Mabilangan, and Seung-Tak Ryu School of Electrical Engineering, KAIST</p>
WP-313	<p><b>Design and Analysis of a Cascaded Floating Inverter Amplifier Based 2nd-Order Noise-Shaping SAR ADC</b> Jang Su Hyeon and Hyeon June Kim Seoul National University of Science &amp; Technology</p>
WP-314	<p><b>A Hybrid Recording System with 10kHz-BW 630mVpp 84.6dB-SNDR 173.3dB-FOMSNDR and 5kHz-BW 114dB-DR for Simultaneous ExG and Biocurrent Acquisition</b> Seokhan Jeong<sup>1</sup>, Taeryoung Seol<sup>2</sup>, and Junghyup Lee<sup>1</sup> <sup>1</sup>DGIST, <sup>2</sup>Georgia Institute of Technology</p>
WP-315	<p><b>A 7T1C 5644 PPI OLED on Silicon Pixel Circuit with 1.2V and 5.5V Transistors in 28nm CMOS Process</b> Hyeon-Ji Lee, Chang-Hun Lee, and Byong-Deok Choi Department of Electronic Engineering, Hanyang University</p>
WP-316	<p><b>A Wide-Lock-In-Range and Low-Jitter 12–14.5 GHz SSPLL Using a Low-Power Frequency-Disturbance-Detecting and Correcting Loop</b> Young Jun Kim, Si Heon Lee, Tae Hyub Kim, and Younghyun Lim School of Semiconductor Engineering, Kyung Hee University</p>
WP-317	<p><b>A Calibration-Free VCO-<math>\Delta\Sigma</math> ADC with PVT-Insensitive Frequency-Locked Differential Regulation Scheme for Multi-Channel ExG Acquisition</b> Sehwan Lee<sup>1,2</sup>, Kyuhyeon Park<sup>1</sup>, and Junghyup Lee<sup>1</sup> <sup>1</sup>DGIST, <sup>2</sup>Samsung Electronics Co., Ltd.</p>



WP-318	<p><b>ADC-Free Neuron based on Page Buffer for Bit-Sliced Neuromorphic Systems</b> Jinhyeok Kim<sup>1,4</sup>, Yoon Kim<sup>1,3,4</sup>, and Minsuk Koo<sup>2,3,4</sup> <sup>1</sup>School of Electrical and Computer Engineering, University of Seoul, <sup>2</sup>School of Advanced Fusion Studies, University of Seoul, <sup>3</sup>IM Electronics co., <sup>4</sup>Center for Semiconductor Research, University of Seoul</p>
WP-319	<p><b>Hybrid LDO Having Small-Output Ripple and Fast Settling at 0.5V Supply Using Dynamic Gate-Voltage Generation and Fast-PD Decision</b> Seungwan Kim and Younghyun Lim School of Semiconductor Engineering, Kyung Hee University</p>
WP-320	<p><b>Design of Programmable-Gain Amplifier for Precise Measurement of Dielectric Absorption Voltage Recovery in On-Chip Capacitors</b> Joo-Sun Lee, Yong-Jin Kim, and Byong-Deok Choi Department of Electronic Engineering, Hanyang University</p>
WP-321	<p><b>60GHz Dual-Core Class-F Push-Push VCO with Dual Path Voltage Control</b> Joon-Hyuk Moon, Ye-Won Jeon, Jun-Kyo Park, Tae-Jeong Kim, and Byung-Sung Kim RF Microelectronic Design Lab., Sungkyunkwan University</p>
WP-322	<p><b>LPDDR 인터페이스용 NRZ/PAM-4 듀얼 모드 송신기 설계</b> 김승균<sup>1</sup>, 조항민<sup>2</sup>, 이원영<sup>1</sup> <sup>1</sup>서울과학기술대학교 스마트ICT융합공학과, <sup>2</sup>한국전자통신연구원</p>
WP-323	<p><b>A SiC MOSFET Gate Driver Employing an Adaptive Soft Turn-Off Current and a Current Slope-to-Digital Converting Technique</b> Geonwoo Park<sup>1</sup>, Jinman Myung<sup>1</sup>, Yoseph Kim<sup>1</sup>, Seungjik Lee<sup>2</sup>, and Ilku Nam<sup>1</sup> <sup>1</sup>Department of Electrical Engineering, Pusan National University, <sup>2</sup>Analog Devices Korea</p>
WP-324	<p><b>A Compact Fractional Output Divider with Time-Multiplexed INL Detection Achieving -75 dBc Worst-Case Spur over 0.64–0.90 V</b> Jiwon Shin, Yoona Lee, and Woo-Seok Choi Department of Electrical and Computer Engineering, Seoul National University</p>



WP-325	<p><b>A D-Band Compact, Power Efficiency X8 Frequency Multiplier With 112–172 GHz Output 3-dB Bandwidth in 28-nm Bulk CMOS</b></p> <p>Dong-Yeol Yang, Ye-won Jeon, and Byung-Sung Kim RF Microelectronic Design Lab., Sungkyunkwan University</p>
WP-326	<p><b>Design of a Hybrid Step-Down Converter with Inductor Current Reduction</b></p> <p>Seungjin Baek<sup>1</sup>, Seunghoon Lee<sup>1</sup>, Jusung Kim<sup>2</sup>, and Kunhee Cho<sup>1</sup> <sup>1</sup>Department of Semiconductor Convergence Engineering, Sungkyunkwan University, <sup>2</sup>Division of Electronic and Semiconductor Engineering, Ewha Womans University</p>
WP-327	<p><b>CTCAM-Based HW Friendly Image Classification Model</b></p> <p>김동휘, 김수민, 임현기, 박주환, 최연우, 서영석, 홍상훈 경희대학교 전자공학과</p>
WP-328	<p><b>A Galvanically Isolated High Speed Switching Gate Driver for Low-to-Medium Voltage Wide-Bandgap Semiconductor</b></p> <p>Sangin Choi and Kunhee Cho Department of Semiconductor Convergence Engineering, Sungkyunkwan University</p>
WP-329	<p><b>A 12-b Fully-Differential Ring-Amp-Based 100-MS/s Pipelined SAR ADC</b></p> <p>Jisu Kim<sup>1</sup>, Taeho Lee<sup>2</sup>, and Jun-Eun Park<sup>1</sup> <sup>1</sup>Department of Electrical and Computer Engineering Sungkyunkwan University, <sup>2</sup>Department of Semiconductor Convergence Engineering Sungkyunkwan University</p>
WP-330	<p><b>Wideband High-Performance CMOS Cascode Frequency Down Converters</b></p> <p>Hosung Kang, Seungyun Han, and Jihoon Kim Kyonggi University</p>
WP-331	<p><b>Skew-Detecting Method for Time-Interleaved SAR ADC</b></p> <p>Joonhyun Park and Hyungil Chae Konkuk University</p>



WP-332	<p><b>A 56-Gb/s PAM4 Receiver Using Injection-Based Baud-Rate CDR With Jointly Adaptive AFE</b> 박민수, 전정훈 Department of Electrical and Computer Engineering, Sungkyunkwan University</p>
WP-333	<p><b>전압 결합 방식 및 전류 결합 방식 동시에 사용된 밀리미터파 CMOS 도허티 전력증 폭기 설계</b> 빈수현, 최영찬, 양영구 성균관대학교 전자전기컴퓨터공학과</p>
WP-334	<p><b>An eMRAM-Based True Random Number Generator Using a Digitally Controlled Delay Line</b> Seunghwa Hyun and Jongsun Park Department of Electrical Engineering, Korea University</p>
WP-335	<p><b>Wireless Network of Distributed Neural Interface</b> Joonyoung Lim, Jong-hyun Park, Gwang-ho Choi, Seok-won Joo, and Yoon-kyu Song Graduate School of Convergence Science and Technology, Seoul National University</p>
WP-336	<p><b>Adaptive Spike Detecting Circuit for Wireless Brain Implant Neural Interface IC</b> Joonyoung Lim, Jong-hyun Park, Gwang-ho Choi, Seok-won Joo, and Yoon-kyu Song Graduate School of Convergence Science and Technology, Seoul National University</p>
WP-337	<p><b>Feasibility Validation of a Domain-Specific Accelerator Integrated into an Open-Source RISC-V SoC</b> Dowon Kim, Dongbeom Son, Dongeon Won, and Jungwook Choi Hanyang University</p>
WP-338	<p><b>D-Band Frequency Multiplier for Wireless Communications in 28-nm CMOS FDSOI Process</b> 김재관<sup>1</sup>, 서문교<sup>2</sup> <sup>1</sup>성균관대학교 반도체융합공학과, <sup>2</sup>성균관대학교 전자전기공학부</p>



---

WP-385

**A 97.5%-Efficiency Hybrid Dual-Path Buck Converter with Self-Balancing**

Hyeon Gyu Park and Young-Kyun Cho

Department of Radio and Information and Communication Engineering,  
Chungnam National University

---



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE2-2 (5층, 로비)

## [WP] 포스터세션

### C. Material Growth & Characterization 분과

WP-036	<p><b>Doping-Dependent Ferroelectric Properties of Al Doped HfO<sub>2</sub> Thin Films for FeFET Applications</b></p> <p>Hyun Gon Pyo<sup>1,2</sup> and Cheol Seong Hwang<sup>1,2</sup></p> <p><sup>1</sup>Department of Materials Science and Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>
WP-037	<p><b>Overcoming Intrinsic Thermal Instability in MoS<sub>2</sub> Monolayer via High-Pressure CVD Growth</b></p> <p>Seok joon Yun and Takmo Jeong</p> <p>University of Ulsan</p>
WP-038	<p><b>공정 변수의 복합적 제어를 통한 고결정성·저결함 MoS<sub>2</sub> 박막의 합성</b></p> <p>황준연, 원종서, 이재원, 허정윤, 홍웅기</p> <p>단국대학교 파운드리공학과</p>
WP-039	<p><b>Atomic Layer Deposition of Molybdenum Carbide and Substrate-Dependent Reduction to Metallic Molybdenum.</b></p> <p>안광용<sup>1</sup>, 구본욱<sup>1</sup>, Kieran G Lawford<sup>2</sup>, Seán T. Barry<sup>2</sup>, and Han-Bo-Ram Lee<sup>1</sup></p> <p><sup>1</sup>Department of Material Science and Engineering, Incheon National University, <sup>2</sup>Department of Chemistry, Carleton University</p>
WP-040	<p><b>Stoichiometry-Engineered Binary Chalcogen Thin Films Enabled by Integrated Synthetic Approach</b></p> <p>Gayeon Lee<sup>1</sup>, Namwook Hur<sup>2</sup>, Changhwan Kim<sup>2</sup>, Seonguk Yang<sup>1</sup>, and Joonki Suh<sup>1</sup></p> <p><sup>1</sup>Department of Chemical and Biomolecular Engineering, KAIST, <sup>2</sup>Department of Materials Science and Engineering, UNIST</p>



WP-041	<p><b>Study on the Efficiency of Deuterium Annealing for Various Process Durations</b> Min-Woo Kim, Hyo-Jun Park, Eui-Cheol Yun, Sang-Min Kang, Da-Eun Bang, Dol Sohn, and Jun-Young Park School of Semiconductor Engineering, Chungbuk National University</p>
WP-042	<p><b>Highly Crystalline <math>ZrO_2</math> Films under 2 nm by Atomic Layer Modulation</b> Wonjoong Kim<sup>1</sup>, Ngoc Le Trinh<sup>1</sup>, Bonwook Gu<sup>1</sup>, Dohyun Kim<sup>1</sup>, Byung-ha Kwak<sup>2</sup>, Hyun-Mi Kim<sup>3</sup>, Hyeongkeun Kim<sup>3</sup>, Youngho Kang<sup>1</sup>, Il-Kwon Oh<sup>2</sup>, and Han-Bo-Ram Lee<sup>1</sup> <sup>1</sup>Department of Materials Science and Engineering, Incheon National University, <sup>2</sup>Department of Electrical and Computer Engineering, Ajou University, <sup>3</sup>Electronic Convergence Materials and Devices Research Center, KETI</p>
WP-043	<p><b>Multi-Zone Thermally Decoupled MOCVD for Low-Temperature <math>MoS_2</math> Synthesis</b> Jongseo Won, Jaewon Lee, Jungyoon Hur, Junyeon Hwang, and Woonggi Hong Department of Foundry Engineering, Dankook University</p>
WP-044	<p><b>Van der Waals High-<math>k</math> Crystalline Lanthanum Oxychloride Integration for Superior Switching 2D Transistor</b> Changjun Park<sup>1</sup>, Habin Baek<sup>2</sup>, Hanbin Cho<sup>1</sup>, Jing Huang<sup>3</sup>, Kyungmin Ko<sup>4</sup>, Chanho Lee<sup>2</sup>, Sangwoo Park<sup>2</sup>, Soobeom Shin<sup>2</sup>, Hu Young Jeong<sup>2</sup>, Jun Kang<sup>3</sup>, and Joonki Suh<sup>1</sup> <sup>1</sup>Department of Chemical &amp; Biomolecular Engineering, KAIST, <sup>2</sup>Graduate School of Semiconductor Materials and Devices Engineering, UNIST, <sup>3</sup>Beijing Computational Science Research Center, <sup>4</sup>Department of Materials Science and Engineering, Seoul National University</p>
WP-045	<p><b>Electro-Optical Switching Behavior of <math>VO_2(M)</math> Thin Films for Integrated Photonic Modulators</b> Namhoon Kim<sup>1,2</sup>, Jaehyeon Gyeong<sup>1</sup>, Heonjin Choi<sup>2</sup>, and Donghee Park<sup>1</sup> <sup>1</sup>Center for Quantum technology, Post-Silicon Semiconductor Institute, KIST, <sup>2</sup>Department of Materials Science and Engineering, Yonsei University</p>



WP-046	<p><b>Understanding Rapid Growth Mechanism of MOCVD-Grown Wafer-Scale MoS<sub>2</sub> under BEOL Compatible Temperature</b></p> <p>Taehyeon Kim<sup>1,2,3</sup>, Jaemin Myoung<sup>1,2,3</sup>, Taesung Kim<sup>4</sup>, and Jihun Mun<sup>1</sup></p> <p><sup>1</sup>Strategic Technology Research Institute, KRISS, <sup>2</sup>SKKU Advanced Institute of Nanotechnology (SAINT), Sungkyunkwan University, <sup>3</sup>Department of Nano Science and Technology, Sungkyunkwan University, <sup>4</sup>School of Mechanical Engineering, Sungkyunkwan University</p>
WP-047	<p><b>Epitaxial Synthesis of Highly Crystalline RuO<sub>2</sub> Thin Films via RF-Magnetron Sputtering</b></p> <p>Min-Seok Kim<sup>1,2</sup>, Jun-Hyeong Park<sup>1,2</sup>, Dong Hyun Lim<sup>1,3</sup>, Jun Min Suh<sup>2,4</sup>, Ho Won Jang<sup>2</sup>, Seung-Hyub Baek<sup>1,5</sup>, and Tae Heon Kim<sup>1,5</sup></p> <p><sup>1</sup>Electronic and Hybrid Materials Research Center, KIST, <sup>2</sup>Department of Materials Science and Engineering, Research Institute of Advanced Materials, Seoul National University, <sup>3</sup>Department of Semiconductor Engineering, Seoul National University of Science &amp; Technology, <sup>4</sup>School of Transdisciplinary Innovations, Seoul National University, <sup>5</sup>Division of Nanoscience and Technology, KIST School, University of Science and Technology</p>
WP-048	<p><b>Temperature-Dependent Phase Transition in WS<sub>2</sub> for Reinforcing Band-to-Band Tunneling and Photoreactive Random Access Memory Application</b></p> <p>Hyun Woo Shim<sup>1</sup>, Gun Hoo Woo<sup>2</sup>, Jin Il Cho<sup>2</sup>, and Tae Sung Kim<sup>1</sup></p> <p><sup>1</sup>School of Semiconductor Convergence Engineering, Sungkyunkwan University, <sup>2</sup>Memory Division, Samsung Electronics Co., Ltd.</p>
WP-049	<p><b>The Preparation of Trans-2-Fluoro-3-(Trifluoromethyl)oxirane for Plasma-Based Dry Etching</b></p> <p>김성미<sup>1,2</sup>, 홍유진<sup>1</sup>, 오명석<sup>1</sup>, 채희엽<sup>2</sup>, 장봉준<sup>1</sup></p> <p><sup>1</sup>한국화학연구원 계면재료 화학공정 연구센터, <sup>2</sup>성균관대학교 화학공학과</p>
WP-050	<p><b>Anion-Controlled Transition Metal-Based Catalysts for Sustainable Chemical Processes</b></p> <p>So Hyeon Kwon, Jaeyong Lee, Hwiyoung Kwon, Daeun Kim, Yubin Choi, and Haeri Lee</p> <p>Department of Chemistry, Hannam University</p>



WP-051	<p><b>Role of Intermediates in Salt-Assisted CVD Growth of Molybdenum Disulfide</b> Chanmin Park<sup>1</sup>, YongJu Kim<sup>1</sup>, Jaewoo Ku<sup>1</sup>, Hyeonryul Lee<sup>2</sup>, Sooncheol Kwon<sup>3</sup>, and Minsu Kim<sup>1</sup></p> <p><sup>1</sup>Department of Advanced Materials Engineering, Kyonggi University, <sup>2</sup>Department of Advanced Battery Convergence Engineering, Dongguk University, <sup>3</sup>Department of Energy and Materials Engineering, Dongguk University</p>
WP-052	<p><b>Thickness-Driven Evolution of Crystallographic Symmetry and the Resulting Domain Twinning in Epitaxial Perovskite Oxide (001) Thin Films</b> Dong-Hun Han<sup>1,2</sup>, Jaebaek Ju<sup>1,3</sup>, Donghyeon Lim<sup>1,4</sup>, Ho Won Jang<sup>2,5</sup>, Tae Heon Kim<sup>1,6</sup>, and Seung-Hyub Baek<sup>1,6</sup></p> <p><sup>1</sup>Electronic and Hybrid Materials Research Center, KIST, <sup>2</sup>Department of Materials Science and Engineering, Research Institute of Advanced Materials, Seoul National University, <sup>3</sup>Department of Materials Science and Engineering, Korea University, <sup>4</sup>Department of Semiconductor Engineering, Seoul National University of Science &amp; Technology, <sup>5</sup>Advanced Institute of Convergence Technology, Seoul National University, <sup>6</sup>Division of Nanoscience and Technology, KIST School, University of Science and Technology</p>
WP-053	<p><b>Thermal Conductivity Measurements of Nickel-Based Alloy Thin Films with Different Alloy Compositions</b> Minkyu Je, Ajin Jo, Taeyeon Kim, Chan Kim, Jihyun Kim, Dongwoo Lee, and Jungwan Cho School of Mechanical Engineering, Sungkyunkwan University</p>
WP-054	<p><b>Thermal Characterization of Sputtered HfO<sub>2</sub> Thin Films on Si Using Frequency-Domain Thermoreflectance</b> Hyeokje Kim, Euimin Cheong, Taeyeon Kim, Jihyun Kim, Dongwoo Lee, and Jungwan Cho School of Mechanical Engineering, Sungkyunkwan University</p>



WP-055	<p><b>Bandgap and Work Function in Semiconducting HfSe2 Films</b></p> <p>Mincheol Kim<sup>1,2,3</sup>, Tae Gyu Rhee<sup>1,3</sup>, Young Rok Khim<sup>1</sup>, Yeong Gwang Khim<sup>1,2</sup>, Young Hoon Khim<sup>1</sup>, Dang Nguyen Hoang<sup>4</sup>, Nguyen Huu Lam<sup>4</sup>, Ganbat Duvjir<sup>4</sup>, Jungdae Kim<sup>4</sup>, Rovi Angelo Beloya Villaos<sup>5</sup>, Feng-Chuan Chuang<sup>5</sup>, and Young Jun Chang<sup>1</sup></p> <p><sup>1</sup>Department of Physics, University of Seoul, <sup>2</sup>Department of Smart Cities, University of Seoul, <sup>3</sup>KIST, <sup>4</sup>Department of Physics and Energy Harvest-Storage Research Center, University of Ulsan, <sup>5</sup>Center for Theoretical and Computational Physics, National Sun Yat-sen University</p> <p><b>오비탈 전류의 분극제어를 통한 무자기장 수직자화 스위칭</b></p> <p>정건우<sup>1</sup>, 윤성종<sup>1</sup>, 전홍원<sup>1</sup>, 우다은<sup>1</sup>, 조홍래<sup>1</sup>, 김우진<sup>1</sup>, 양희창<sup>2</sup>, 김혜진<sup>3</sup>, 이원익<sup>2</sup>, 박민서<sup>2</sup>, 전세윤<sup>3</sup>, 최현경<sup>2</sup>, 김종윤<sup>2</sup>, 김동현<sup>3</sup>, 엄기태<sup>1</sup>, 이수길<sup>1</sup></p> <p><sup>1</sup>가천대학교 반도체공학과, <sup>2</sup>가천대학교 반도체전자공학부 차세대반도체공학전공, <sup>3</sup>가천대학교 반도체전자공학부 전자공학전공</p> <p><b>Growth and Characterization of Two-Dimensional Molybdenum Disulfide by Using Metal Organic Chemical Vapor Deposition</b></p> <p>Jeongseo Moon<sup>1,2</sup>, Won Young Jang<sup>3</sup>, Kyung Rim Kang<sup>4</sup>, Min-jae Lee<sup>3</sup>, Hong Seok Ko<sup>4</sup>, Seong Bin You<sup>5</sup>, Kang Bok Ko<sup>2</sup>, Bo-In Park<sup>1,2,3</sup>, Chel-jong Choi<sup>1,2,3</sup>, and Keun Heo<sup>1,2,3</sup></p> <p><sup>1</sup>School of Semiconductor and Chemical Engineering, Jeonbuk National University, <sup>2</sup>Semiconductor Physics Research Center, Jeonbuk National University, <sup>3</sup>Department of Semiconductor Science and Technology, Jeonbuk National University, <sup>4</sup>Department of Electronic Engineering, Jeonbuk National University, <sup>5</sup>Division of Advanced Materials Engineering, Jeonbuk National University</p> <p><b>Titanium Carbide MXene Based Composite for Multi-Directional Heat Spreader</b></p> <p>Seoyeon Choi<sup>1</sup>, Young Ho Jin<sup>1</sup>, Yeongcheol Park<sup>2</sup>, Jae Hun Seol<sup>2</sup>, and Soon-Yong Kwon<sup>2</sup></p> <p><sup>1</sup>Department of Materials Science and Engineering and Graduate School of Semiconductor Materials and Devices Engineering, UNIST, <sup>2</sup>Department of Mechanical Engineering, GIST</p>
WP-056	
WP-057	
WP-058	



WP-059	<p><b>Precursor-Driven Morphological Control of MXenes for High-Performance EMI Shielding and Energy Storage</b></p> <p>Jaeeun Park<sup>1</sup>, Ju-Hyoung Han<sup>1</sup>, Yujin Chae<sup>1</sup>, Mincheal Kim<sup>2</sup>, Juwon Han<sup>1</sup>, Younggeun Jang<sup>1,3</sup>, Young Ho Jin<sup>1</sup>, Jaewon Wang<sup>1</sup>, Zonghoon Lee<sup>1,3</sup>, EunMi Choi<sup>2</sup>, and Soon-Yong Kwon<sup>1,4</sup></p> <p><sup>1</sup>Department of Materials Science and Engineering, UNIST, <sup>2</sup>Department of Electrical Engineering, UNIST, <sup>3</sup>Center for Multidimensional Carbon Materials, IBS, <sup>4</sup>Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p> <p><b>WS<sub>2</sub>-MoSe<sub>2</sub> Heterostructures Grown by Two-Step Metal-Organic Chemical Vapor Deposition</b></p> <p>Chaehui Lim<sup>1,2</sup>, Wonchan Lee<sup>1,2</sup>, Yunjung Cho<sup>1,2</sup>, Seohee Park<sup>2,3</sup>, and Seunguk Song<sup>1,2</sup></p> <p><sup>1</sup>Department of Energy Science, Sungkyunkwan University, <sup>2</sup>Center for 2D Quantum Heterostructures, IBS, Sungkyunkwan University, <sup>3</sup>Department of Chemistry, Sungkyunkwan University</p> <p><b>Defect-Engineered Epitaxial Growth of WS<sub>2</sub> Monolayer for 2D Optoelectronics</b></p> <p>Yunjung Cho<sup>1,2</sup>, Wonchan Lee<sup>1,2</sup>, Seohee Park<sup>2,3</sup>, and Seunguk Song<sup>1,2</sup></p> <p><sup>1</sup>Department of Energy Science, Sungkyunkwan University, <sup>2</sup>Center for 2D Quantum Heterostructures, IBS, Sungkyunkwan University, <sup>3</sup>Department of Chemistry, Sungkyunkwan University</p> <p><b>Understanding the First-Firing Mechanism in Ge-Te Based Binary Ovonic Threshold Switches through Atomic-Scale Analysis and First-Principles Calculations</b></p> <p>Young-Min Kim<sup>1,2</sup>, Siwon Park<sup>1,2</sup>, Sangyeop Kim<sup>1,2</sup>, and Jong-Souk Yeo<sup>1</sup></p> <p><sup>1</sup>School of Integrated Technology, College of Computing, Yonsei University, <sup>2</sup>BK21 Graduate Program in Intelligent Semiconductor Technology</p> <p><b>집속 이온빔 패터닝을 통한 InGaN/GaN 양자점의 선택적 영역 성장</b></p> <p>김바울, 조용훈</p> <p>한국과학기술원 물리학과</p>
WP-060	
WP-061	
WP-062	
WP-063	



WP-064	<p><b>Investigation of Multiferroic <math>\epsilon</math>-<math>\text{Ga}_{2-x}\text{Fe}_x\text{O}_3</math> Thin Films Grown by Mist CVD</b></p> <p>Young Soo Hwang, Ha Young Kang, Jae Heon Jung, and Roy Byung Kyu Chung</p> <p>School of Materials Science and Engineering, Kyungpook National University</p>
WP-065	<p><b>Carbon Coated–Nitride MAXene/MoS<sub>2</sub> Heterogeneous Catalyst for Hydrogen Evolution Reaction</b></p> <p>Yujin Chae<sup>1</sup>, Yeoseon Sim<sup>1</sup>, Shi-Hyun Seok<sup>1</sup>, Jaeeun Park<sup>1</sup>, Ju-Hyoung Han<sup>1</sup>, Young Ho Jin<sup>1</sup>, and Soon-Yong Kwon<sup>1,2</sup></p> <p><sup>1</sup>Department of Materials Science and Engineering, UNIST, <sup>2</sup>Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p>
WP-066	<p><b>Spatially Confined Vapor–Phase Growth of MoTe<sub>2</sub>–WS<sub>2</sub> Lateral Heterostructure</b></p> <p>Inbae Song<sup>1,2</sup>, Yunjung Cho<sup>1,2</sup>, Kyungwu Kwon<sup>1,2</sup>, Wonchan Lee<sup>1,2</sup>, and Seunguk Song<sup>1,2</sup></p> <p><sup>1</sup>Department of Energy Science, Sungkyunkwan University, <sup>2</sup>Center for 2D Quantum Heterostructures, IBS, Sungkyunkwan University</p>
WP-067	<p><b>In Situ Observation of a Confined Nucleation and Growth of Bi Particles in <math>\delta</math>-Bi<sub>2</sub>O<sub>3</sub> Nanosheets</b></p> <p>Hyeon Jin Choi, Yun Jae Jeong, Jin Young Kim, Chan Hee Hwang, and Young Heon Kim</p> <p>Graduate School of Analytical Science and Technology, Chungnam National University</p>
WP-068	<p><b>Ce-Induced Lattice Expansion of BaZrO<sub>3</sub> for Advanced Substrate</b></p> <p>Biprojit Sana, Dong Whee Kim, Hei Woong Lee, and Yoon Seok Oh</p> <p>Department of Physics, UNIST</p>
WP-069	<p><b>Quantitative Analysis of Hydrogen in H<sub>x</sub>VO<sub>2</sub></b></p> <p>Byungho Lee<sup>1,2</sup>, Jinwook Lee<sup>1,2</sup>, and Woo Jin Kim<sup>1,2</sup></p> <p><sup>1</sup>Department of Materials Science and Engineering, Pusan National University, <sup>2</sup>Institute of Materials Technology, Pusan National University</p>
WP-070	<p><b>One-Step SiO<sub>2</sub> Coating for Reliable Insulation in High-Density Probe</b></p> <p>Minsoo Jang and Doowon Lee</p> <p>Division of Electrical, Electronic and Control Engineering, Kongju National University</p>



WP-071	<p><b>Epitaxial Growth of Twin-Free Orthorhombic <math>\text{SrCuO}_2</math> Thin Films</b></p> <p>Jiwon Lee<sup>1,2</sup>, Jaewoo Lee<sup>1,2</sup>, Hyungmok Lee<sup>1,2</sup>, and Woo Jin Kim<sup>1,2</sup></p> <p><sup>1</sup>Department of Materials Science and Engineering, Pusan National University, <sup>2</sup>Institute of Materials Technology, Pusan National University</p>
WP-072	<p><b>Fluorine-Doped N-Type <math>\alpha\text{-Ga}_2\text{O}_3</math> and Its Phase Stability</b></p> <p>Choi Yoonho and Roy Byung Kyu Chung</p> <p>Department of Materials Science &amp; Engineering, Kyungpook National University</p>
WP-073	<p><b>Electrical Properties of AlN</b></p> <p>Do Hyun Kim<sup>1</sup>, Ji Soo Jang<sup>2</sup>, Nimpah Sarkar<sup>1</sup>, Da Hyung Kim<sup>1</sup>, Seon Namgung<sup>1</sup>, Taenam Kwon<sup>1</sup>, Kunook Chung<sup>1</sup>, Se Young Park<sup>3</sup>, Seung Hyub Baek<sup>2</sup>, Tae Heon Kim<sup>2</sup>, and Yoon Seok Oh<sup>1</sup></p> <p><sup>1</sup>UNIST, <sup>2</sup>KIST, <sup>3</sup>Department of Physics, Soongsil University</p>
WP-074	<p><b>TCAD Simulation Based Modeling of Short-Wave Infrared PbS CQD Photodiode</b></p> <p>Eunsoo Lim<sup>1</sup>, Junghun Kim<sup>2</sup>, and Jiwon Lee<sup>1,2</sup></p> <p><sup>1</sup>Department of Semiconductor Engineering, POSTECH, <sup>2</sup>Graduate School of Semiconductor Technology, POSTECH</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE2-2 (5층, 로비)

## [WP] 포스터세션

### L. Analog Design 분과

WP-171	<p><b>A PVT-Compensated LDO with a Process-Calibration BGR and a Temperature-Coefficient Cancelled BMR</b></p> <p>황중환, 류지환, 김민우, 김윤수, 염인선, 최명현, 양병도 총북대학교 전자정보대학 반도체공학부</p>
WP-172	<p><b>Wide-Range, Fast-Locking Referenceless CDR based on BFSM</b></p> <p>Jinwoo Hong, Jongmin Park, and Jinwook Burm Department of Electronic Engineering, Sogang University</p>
WP-173	<p><b>A 12-bit Column-Parallel Two-Step TDC-Assisted SAR ADC for CIS</b></p> <p>Jongmin Kim, Wooseok Jung, and Jinwook Burm Department of Electronic Engineering, Sogang University</p>
WP-174	<p><b>All-Digital CDR with Fast Locking and Improved PI Linearity Using an Injection-Locked Ring Oscillator</b></p> <p>Jimin Kim, Taeuk Kim, and Jinwook Burm Department of Electronic Engineering, Sogang University</p>
WP-175	<p><b>A High PSR, Fast Transient Response Dual-Pass Transistor Capacitor-Less LDO for X-Ray Detector Applications</b></p> <p>Hyeonjae Yoo<sup>1</sup>, Seungpyo Oh<sup>2</sup>, Dooho Kim<sup>1</sup>, Kang Heo<sup>1</sup>, Kyunghun Yoon<sup>1</sup>, and Jooyeol Rhee<sup>2</sup> <sup>1</sup>Advanced Technology R&amp;D Center, Vieworks Co., <sup>2</sup>College of Semiconductor, Gachon University</p>
WP-176	<p><b>임베디드 플래시 구동을 위한 복구시간 감지 기반 레귤레이터 내장형 차지 펌프</b></p> <p>김준서<sup>1,4</sup>, 김정남<sup>2,4</sup>, 김윤<sup>2,4,5</sup>, 구민석<sup>3,4,5</sup> <sup>1</sup>서울시립대학교 지능형반도체학과, <sup>2</sup>서울시립대학교 전자전기컴퓨터공학부, <sup>3</sup>서울시립대학교 첨단융합학부, <sup>4</sup>서울시립대학교 반도체 연구센터(UOS-FAB), <sup>5</sup>주식회사 IM전자</p>



WP-177	<p><b>A Low-Power RF-DC Converter Using an Adaptive Architecture to Achieve a 43-dB Wide-Input-Range for RF Energy Harvesting</b> Yeji Han and Ickjin Kwon School of Electrical and Computer Engineering, Ajou University</p>
WP-178	<p><b>Comparator Offset Calibration for Single-Channel Speculative Loop-Unrolled SAR ADC in 28-nm CMOS</b> Dong-Un Jin and Min-Seong Choo Department of Electronic Engineering, Hanyang University</p>
WP-179	<p><b>Power and Area Efficient Time-Domain ADC</b> Youngwoo Kwon and Hyungil Chae Konkuk University</p>
WP-180	<p><b>A C-CI SAR ADC with Pulse-Gating Charge-Injection Cell</b> Junmin Park and Hyungil Chae Konkuk University</p>
WP-181	<p><b>A High-Resolution Supply-Noise-Insensitive Linear Digital-to-Time Converter for Low-Noise Fractional Dividers</b> Yuna Hwang<sup>1,2</sup> and Woo-Seok Choi<sup>1,2</sup> <sup>1</sup>Department of Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>
WP-182	<p><b>A Study on Extremely Low-Power Design and Operation for High-Performance Digital Pixel Sensor</b> Jaehun Jeong, Sanggwon Lee, Yong-Suk Choi, Yeongseok Shim, Gihwan Cho, Youna Lee, Bumjun Kim, Su-Hyun Han, Heesung Shim, Min-Woong Seo, Jae-kyu Lee, and Jonghyun Go Semiconductor R&amp;D Center, Samsung Electronics Co., Ltd.</p>
WP-183	<p><b>아날로그 부궤환을 이용하여 주변광 간섭을 상쇄하는 PPG 아날로그 수신단 증폭기</b> Minji Kim and Ji-Yong Um Department of Medical IT Convergence Engineering, Kumoh National Institute of Technology</p>



WP-184	<p><b>A High-Power-Supply-Rejection Capless Low-Dropout Regulator with Extended Bandwidth</b></p> <p>Min-Seo Kim, You-Chan Kim, Hui-Won Jeong, Joon-Ho Im, and Byong-Deok Cho</p> <p>Department of Electronic Engineering, Hanyang University</p>
WP-185	<p><b>Ultra-Low Quiescent Current OCL-LDO With Fast-Transient Response</b></p> <p>Dong-Wook Jeong and Ickjin Kwon</p> <p>Department of Electrical and Computer Engineering, Ajou University</p>
WP-186	<p><b>보조 패스 트랜지스터의 방전 전류 및 다이오드 커넥티드 MOS 이용한 빠른 과도응답을 가지는 Ultra-Low-Power OCL-LDO 레귤레이터 설계</b></p> <p>김주훈, 권익진</p> <p>아주대학교 전자공학과</p>
WP-187	<p><b>12-Bit, 640MSps TI-SAR ADC With Clock Distribution Layout Technique for WiFi-6 Application</b></p> <p>안상준, 김선우, 황인성, 여중기, 정보근, 백동현, 김영진</p> <p>한국항공대학교 Nanowave-Integrated Circuit and System Lab</p>
WP-189	<p><b>전력반도체 게이트 구동 드라이버의 Isolation을 위한 구동 환경 변화에 둔감한 신호 변조 회로</b></p> <p>김남현<sup>1,2</sup>, 심민섭<sup>2</sup>, 김기현<sup>1</sup>, 송기남<sup>1</sup></p> <p><sup>1</sup>한국전기연구원 파워SoC연구센터, <sup>2</sup>경상국립대학교</p>
WP-190	<p><b>Radiation-Hardened Logic Gate Design Methodology Considering NMOS Dimension Variation under TID Effects</b></p> <p>Serin Lee, Kihyun Kim, and Kyoungho Lee</p> <p>KERI</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE2-2 (5층, 로비)

## [WP] 포스터세션

### N. VLSI CAD 분과

WP-200	<p><b>High-Frequency Clock Generator Design based on Logic Synthesis for Cross-Process Portability</b> Sooah Choi, Jihoon Park, and Jae-Joon Kim Department of Electrical and Computer Engineering, Seoul National University</p>
WP-201	<p><b>A16K: 1.6nm NSFET, FSFET, and CFET Technology Libraries for Chip-Level VLSI Prediction</b> Hwiryeong Kim<sup>1</sup>, Hanmok Park<sup>1</sup>, Mingyun Sun<sup>2</sup>, Yongjin Kwon<sup>2</sup>, Jiyoong Jung<sup>2</sup>, Gahyeon Kim<sup>2</sup>, Gyengjin Kim<sup>2</sup>, Sunmean Kim<sup>1</sup>, and Taigon Song<sup>2</sup> <sup>1</sup>School of Electronics and Electrical Engineering, Kyungpook National University, <sup>2</sup>School of Electronics Engineering, Kyungpook National University</p>
WP-202	<p><b>In-Cell Routability Prediction for Complementary FET Standard Cell Transistor Placement</b> Seo Yeong Mun<sup>1</sup> and Suwan Kim<sup>2</sup> <sup>1</sup>Department of Convergent Biotechnology And Advanced Materials Science, Kyung Hee University, <sup>2</sup>Department of Electronic Engineering, Kyung Hee University</p>
WP-203	<p><b>A Perceptron Hybrid Branch Predictor for Ternary Pipelined Architectures</b> Seonghoon Kim, Hanmok Park, Sunmean Kim, and Taigon Song School of Electronic and Electrical Engineering, Kyungpook National University</p>
WP-204	<p><b>A Hardware-Level Framework for Training and Inference of Capacitive Computing-in-Memory Architecture</b> Changhyeon Park<sup>1,2</sup> and Woo Young Choi<sup>1,2</sup> <sup>1</sup>Department Electrical and Computer Engineering, Seoul National University, <sup>2</sup>Inter-university Semiconductor Research Center, Seoul National University</p>



WP-205	<p><b>Area and Energy-Efficient Architecture for p-Bit Digital Ising Machine</b> Jin Su Kim, Jun Hee Lee, Ji Hoon Park, and Jae Joon Kim Seoul National University</p>
WP-206	<p><b>An RTL-Based General Synthesis Methodology for Device-Independent Ternary Logic Circuits</b> Hanmok Park, Seonghoon Kim, and Taigon Song School of Electronics and Electrical Engineering, Kyungpook National University</p>
WP-207	<p><b>온도를 고려한 정적 타이밍 분석과 임계 경로 변화 분석</b> 조혜양, 박영훈, 정준서, 김강훈, 김현수, 박성범, 김주호 서강대학교 컴퓨터공학과</p>
WP-208	<p><b>SRAM 기반 인메모리 컴퓨팅에서 전력 효율적인 Adder Tree를 위한 아키텍처 및 트랜지스터 수준 설계의 학습 기반 공동 최적화</b> 고다훈<sup>1</sup>, 송민근<sup>1</sup>, 이준서<sup>1</sup>, 우재현<sup>1</sup>, 조형원<sup>1</sup>, Aiganyim Zhalinova<sup>1</sup>, 강성원<sup>2</sup>, 강지수<sup>2</sup>, 김태민<sup>2</sup>, 김태우<sup>2</sup>, 정한율<sup>1</sup> <sup>1</sup>연세대학교 전기전자공학과, <sup>2</sup>Department of Electronic Engineering, Kwangwoon University</p>
WP-209	<p><b>머신러닝 기반 설계 최적화를 이용한 에너지 효율적 SRAM 기반 메모리 내 연산 회로</b> 박세준<sup>1</sup>, 유두현<sup>1</sup>, 고동현<sup>1</sup>, 정우석<sup>1</sup>, 김태성<sup>1</sup>, 한창용<sup>1</sup>, 박관우<sup>2</sup>, 백재승<sup>2</sup>, 장이준<sup>2</sup>, 손승원<sup>2</sup>, 정한율<sup>1</sup> <sup>1</sup>연세대학교 전기전자공학과, <sup>2</sup>Department of Electronic Engineering, Kwangwoon University</p>
WP-210	<p><b>Post-Scaler: Architecture Support for True FP-INT GEMM</b> Jihyun Moon<sup>1,3</sup> and Joon-Sung Yang<sup>1,2,3</sup> <sup>1</sup>Department of Systems Semiconductor Engineering, Yonsei University, <sup>2</sup>Department of Electrical and Electronic Engineering, Yonsei University, <sup>3</sup>BK21 Graduate Program in Intelligent Semiconductor Technology, Yonsei University</p>



WP-211	<p><b>Ancilla-Aware Tiled Architecture for Efficient Surface Code Communication in Fault-Tolerant Quantum Computing</b> Youngjung Kang<sup>1</sup> and Joon-Sung Yang<sup>1,2,3</sup> <sup>1</sup>Department of System Semiconductor Engineering, Yonsei University, <sup>2</sup>Department of Electrical and Electronic Engineering, Yonsei University, <sup>3</sup>BK21 Graduate Program in Intelligent Semiconductor Technology, Yonsei University</p>
WP-212	<p><b>DNN Accelerator Exploiting Slice-Level Sparsity with Bit-Slice Architecture</b> Insu Choi<sup>1</sup> and Joon-Sung Yang<sup>1,2,3</sup> <sup>1</sup>Department of Electrical and Electronic Engineering, Yonsei University, <sup>2</sup>Department of System Semiconductor Engineering, Yonsei University, <sup>3</sup>BK21 Graduate Program in Intelligent Semiconductor Technology, Yonsei University</p>
WP-213	<p><b>자기 지도 학습 기반 테스트 포인트 삽입</b> 박태민<sup>1</sup>, 양준성<sup>1,2,3</sup> <sup>1</sup>연세대학교 전기전자공학과, <sup>2</sup>연세대학교 시스템반도체공학과, <sup>3</sup>연세대학교 지능형반도체IT융합전공</p>
WP-214	<p><b>Automated Layout Optimization for Planar MOSFETs Considering Local Layout Effects (LLE)</b> Ji-hye Yoo<sup>1</sup>, Gaon Lee<sup>2</sup>, June-yeop Lee<sup>1</sup>, and Jong-wook Jeon<sup>1</sup> <sup>1</sup>Department of Electrical and Computer Engineering, Sungkyunkwan University, <sup>2</sup>Department of Display Engineering, Sungkyunkwan University</p>
WP-215	<p><b>Logic Optimization via Reinforcement Learning-Guided Gate Transformation</b> Donghyuk Lee, Hyunmin Jo, and Heechun Park UNIST</p>
WP-216	<p><b>Robust Fusion-Based Acceleration of Attention Training on Edge Hardware</b> Dowon Kwon, Joonseok Kim, Jonghyeon Nam, and Seokhyeong Kang Graduate School of Semiconductor Technology, POSTECH</p>
WP-217	<p><b>LLM-Based Code Augmentation for Generating PPA-Diverse RTL Designs</b> Yeonwoo Shim<sup>1</sup>, Sunsang Gwon<sup>2</sup>, and Seokhyeong Kang<sup>2</sup> <sup>1</sup>Department of Semiconductor Engineering, POSTECH, <sup>2</sup>Department of Electrical Engineering, POSTECH</p>



# 제 33회 한국반도체학술대회

The 33rd Korean Conference on Semiconductors

2026년 1월 27일(화)-30일(금) | 강원도 하이원리조트 그랜드호텔(컨벤션타워)

A Paradigm Shift in Semiconductors for AI Era

WP-218	FPGA 구현을 위한 경량 인공지능 기반 ADC 실시간 보정 구조 설계 강륜 <sup>1</sup> , 김건 <sup>1</sup> , 김동영 <sup>1</sup> , 김수연 <sup>1</sup> , 김신욱 <sup>1</sup> , 박제원 <sup>1</sup> , 김소원 <sup>1</sup> , 임채혁 <sup>1</sup> , 서현아 <sup>1</sup> , 윤정현 <sup>1</sup> , 이주원 <sup>1</sup> , 이해린 <sup>1</sup> , 최우진 <sup>2</sup> , 김어진 <sup>2</sup> , 정민우 <sup>2</sup> , 이명진 <sup>1</sup> <sup>1</sup> 전남대학교 지능전자컴퓨터공학과, <sup>2</sup> 전남대학교 전자컴퓨터공학부
WP-219	고신뢰도 IR Drop 예측을 위한 물리 기반 후처리 전류 인식 보정 및 이방성 필터링 고운 서강대학교 컴퓨터공학과



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE3 (6층, 로비)

## [WP] 포스터세션

### B. Patterning (Lithography & Etch Technology) 분과

WP-001	저 지구온난화지수 HFE-347 이성질체를 이용한 $\text{SiO}_2$ Contact Hole 식각 김민욱 <sup>1,2</sup> , 김창구 <sup>1,2</sup> <sup>1</sup> Department of Chemical Engineering, Ajou University, <sup>2</sup> Department of Energy Systems Research, Ajou University
WP-002	지구온난화지수가 낮은 Fluorinated Alcohol 플라즈마를 이용한 $\text{SiO}_2$ 식각 김준영 <sup>1,2</sup> , 김창구 <sup>1,2</sup> <sup>1</sup> Department of Chemical Engineering, Ajou University, <sup>2</sup> Department of Energy Systems Research, Ajou University
WP-003	Forward Metal-Assisted Chemical Etching for Self-Aligned Recess-Gate $\beta$ - $\text{Ga}_2\text{O}_3$ MESFETs 김지호 <sup>1,2</sup> , 최웅 <sup>1</sup> , 김지현 <sup>1</sup> <sup>1</sup> 서울대학교 화학생물공학부, <sup>2</sup> 삼성전자 DS 메모리사업부
WP-004	Temperature-Dependent HF Physisorption Etching Mechanisms of $\text{SiO}_2$ and $\text{SiN}$ in $\text{NF}_3/\text{H}_2$ Plasma Jungjae Yoo, Taemin Kim, Youngmin Sunwoo, Paul Seo, Hongsik Jeong, and Byungjo Kim Graduate School of Semiconductor Materials and Devices Engineering, UNIST
WP-005	광-보조 습식 세정을 통한 High-NA EUV 마스크 상의 Sn 오염 입자 제거 효율 향상 최웅 <sup>1</sup> , 박제환 <sup>1</sup> , 김문경 <sup>2</sup> , 김지현 <sup>1</sup> <sup>1</sup> 서울대학교 화학생물공학부, <sup>2</sup> 삼성전자 파운드리사업부



WP-006	<p><b>Nanoporous MoS<sub>2</sub> Bio-FET for Artificial Olfaction with Edge-Dominant VOC Sensing</b></p> <p>Subin Lim<sup>1</sup> and Sunkook Kim<sup>2</sup></p> <p><sup>1</sup>Department of Display Engineering, Sungkyunkwan University, <sup>2</sup>School of Advanced Materials Science and Engineering, Sungkyunkwan University</p>
WP-007	<p><b>고종횡비 구조 내 이온-표면 상호작용의 물리적 메커니즘 규명을 위한 분자동역학-AI 융합 시뮬레이션 프레임워크</b></p> <p>선우영민, 이도훈, 홍준표, 김병조</p> <p>울산과학기술원 반도체 소재·부품 대학원</p>
WP-008	<p><b>Explainable AI 기반 NF<sub>3</sub>/H<sub>2</sub> 플라즈마의 SiO<sub>2</sub> 및 SiN 저온 식각 메커니즘 분석</b></p> <p>서바울, 선우영민, 김태민, 유정재, 정홍식, 김병조</p> <p>울산과학기술원 반도체 소재 · 부품 대학원</p>
WP-009	<p><b>Revisiting the Role of Carboxylates in Organotin Carboxylate EUV Resists</b></p> <p>Hyeok Yun, Hayun Kim, Wonchul Kee, and Hyun-Dam Jeong</p> <p>Department of Chemistry, Chonnam National University</p>
WP-010	<p><b>Synthesis and Evaluation of Function-Integrated Inorganic Molecular Resists for EUV Lithography</b></p> <p>Gahyun Lee, Pronab Kumar Singha, Seung-yong Baek, Hyeok Yun, and Hyun-Dam Jeong</p> <p>Department of Chemistry, Chonnam National University</p>
WP-011	<p><b>High-Sensitivity Negative-Tone Tin-Oxo Molecular Resist for EUV Lithography</b></p> <p>Soyeong Heo, Wonchul Kee, and Hyun-Dam Jeong</p> <p>Department of Chemistry, Chonnam National University</p>
WP-012	<p><b>Surface Characterization of Siloxane Molecular Resists: Understanding Chemical Contrast for Next-Generation Lithography</b></p> <p>Jiyoung Bang, Hyeok Yun, Wonchul Kee, Donghwan Kim, and Hyun-Dam Jeong</p> <p>Department of Chemistry, Chonnam National University</p>



WP-013	<p><b>Molecular Tin-Orthosilicates: Synthesis, Characterization, and Electron-Beam Lithography Application for EUV Resists</b></p> <p>Jiyoung Bang<sup>1</sup>, Hyeok Yun<sup>1</sup>, Soyoung Heo<sup>1</sup>, Seung Hwan Kang<sup>2</sup>, Yusun Won<sup>2</sup>, Hyun Tae Jung<sup>2</sup>, and Hyun-Dam Jeong<sup>1</sup></p> <p><sup>1</sup>Department of Chemistry, Chonnam National University, <sup>2</sup>JSI Silicone Inc.</p>
WP-014	<p><b>Synthesis and Structural Characterization of a Monomeric Inorganic Resist for EUV Lithography</b></p> <p>Wonchul Kee<sup>1</sup>, Hayun Kim<sup>1</sup>, Soyeong Heo<sup>1</sup>, Jiyoung Bang<sup>1</sup>, Hyun-Sung Yoon<sup>1</sup>, Seungyong Baek<sup>1</sup>, Gahyun Lee<sup>1</sup>, Hyeok Yun<sup>1</sup>, Eun-Seok Choe<sup>2</sup>, Jung-Hyung Kim<sup>2</sup>, and Hyun-Dam Jeong<sup>1</sup></p> <p><sup>1</sup>Department of Chemistry, Chonnam National University, <sup>2</sup>KRISS</p>
WP-015	<p><b>Radical Generation and Fragmentation Mechanisms of Decomposition Products from <math>C_3F_6O</math> and <math>C_4F_8O</math></b></p> <p>Minji Kim and Sangheon Lee</p> <p>Chemical Engineering and Materials Science, Ewha Woman's University</p>
WP-016	<p><b>Molecular Design and Synthesis of Extreme UV Photoresists Incorporating Unsaturated Carbon Units and Tin Atoms</b></p> <p>Gayoung Kim<sup>1</sup>, Junsik Kim<sup>1</sup>, Sung-Wook Hwang<sup>1</sup>, Dain Park<sup>1</sup>, Yejin Ku<sup>1</sup>, Jinseok Lee<sup>1</sup>, Seokmin Kang<sup>1</sup>, Jiho Kim<sup>3</sup>, Geonwha Kim<sup>3</sup>, Sangsul Lee<sup>3</sup>, and Jin-Kyun Lee<sup>1,2</sup></p> <p><sup>1</sup>Program in Environment and Polymer Engineering, Inha University, <sup>2</sup>Department of Polymer Science and Engineering, Inha University, <sup>3</sup>Pohang Accelerator Laboratory, POSTECH</p>
WP-017	<p><b>Atomic Layer Etching of <math>SiO_2</math> and <math>SiN_x</math> Using Combined Remote and Direct Plasma Processes</b></p> <p>Sung Hyun Lim, So Won Kim, and Hee Chul Lee</p> <p>Department of Advanced Materials Engineering, Tech University of Korea</p>
WP-018	<p><b>저온전자온도 플라즈마를 이용한 EUV 포토레지스트 건식 현상 공정 기술</b></p> <p>김지원<sup>1,4</sup>, 석지후<sup>1,4</sup>, 윤광섭<sup>1,3</sup>, 이태호<sup>4</sup>, 정진욱<sup>2,4</sup>, 안진호<sup>1,4</sup></p> <p><sup>1</sup>한양대학교 신소재공학과, <sup>2</sup>한양대학교 전기공학과, <sup>3</sup>삼성전자 반도체 연구소, <sup>4</sup>극한스 케일·극한물성-이종집적 한계극복 반도체 기술 연구센터</p>



WP-019	<p><b>Reaction-Condition Optimization for Impurity Suppression and Purification of Tin-Oxo Cluster CNU-TOC-01 (4C-C)</b> Seung-Yong Baek, Cheol-Ho Jo, Seung-Hoon Park, and Hyun-Dam Jeong Department of Chemistry, Chonnam National University</p>
WP-020	<p><b>Formulation-Process Optimization Guided by Electron-Beam Evaluation for EUV Resists</b> Seung-Yong Baek, Wonchul Kee, and Hyun-Dam Jeong Department of Chemistry, Chonnam National University</p>
WP-021	<p><b>Efficient Prediction of Wafer-Radius Ion Energy and Angular Distributions with Machine Learning for Plasma Etching</b> Wan-gyu Gwak<sup>1</sup>, Kyeong-Bin Kim<sup>2</sup>, Jongchan Park<sup>3</sup>, Chan-Young Choi<sup>4</sup>, and Eun-ho Lee<sup>1,2,3</sup> <sup>1</sup>Department of Smart Fab. Technology, Sungkyunkwan University, <sup>2</sup>Department of Mechanical Engineering, Sungkyunkwan University, <sup>3</sup>Department of Intelligent Robotics, Sungkyunkwan University, <sup>4</sup>SEMES Co., Ltd.</p>
WP-022	<p><b>Organic-Inorganic Hybrid Positive-Tone Photoresist via MLD for EUV Lithography</b> Junseong Hur<sup>1</sup>, Jaehyuk Lee<sup>2</sup>, Hyeonseok Ji<sup>2</sup>, Nguyen Quang Khanh<sup>2</sup>, Chaerim Kim<sup>2</sup>, Soojin Park<sup>1</sup>, Tran Cuong Dai<sup>2</sup>, Heeseo Kim<sup>2</sup>, and Myung Mo Sung<sup>2</sup> <sup>1</sup>Department of Semiconductor Engineering, Hanyang University, <sup>2</sup>Department of Chemistry, Hanyang University</p>
WP-023	<p><b>Vertical Molecular Wire Structured Hybrid Multilayer Photoresist for Extreme Ultraviolet Lithography Using Molecular Layer Deposition</b> Taeeon Kim<sup>1</sup>, Heemin Kang<sup>2</sup>, Hyeonseok Ji<sup>1</sup>, Jaehyuk Lee<sup>1</sup>, Chaerim Kim<sup>1</sup>, and Myung Mo Sung<sup>1</sup> <sup>1</sup>Department of Chemistry, Hanyang University, <sup>2</sup>Department of Semiconductor Engineering, Hanyang University</p>
WP-024	<p><b>DFT를 이용한 초기 <math>CF_x</math> 라디칼 흡착을 통한 비정질 <math>Si_3N_4</math> 표면에서의 플루오로카본 필름 연구</b> 조미현, 이상현 이화여자대학교 화공신소재공학과</p>



WP-025	<p><b>Development of Fluorinated Protective Layer and Its Integration with Water-Transfer Photolithography for Organic Semiconductor Patterning</b></p> <p>김서연<sup>1</sup>, 김가영<sup>1</sup>, 권유정<sup>1</sup>, 엄준호<sup>3</sup>, 최재학<sup>3,4</sup>, 이진균<sup>1,2</sup></p> <p><sup>1</sup>Program in Environment and Polymer Engineering, Inha University, <sup>2</sup>Department of Polymer Science and Engineering, Inha University, <sup>3</sup>Department of Materials Science and Engineering, Chungnam National University, <sup>4</sup>Department of Polymer Science and Engineering, Chungnam National University</p>
WP-026	<p><b>Multiscale Patterning of Single-Crystal C8-BTBT Enabled by a PDMS Solvent-Diffusion Process</b></p> <p>Seeun Kwon, Sangtae Lee, Dongjun Lee, Bumseo Park, and Insung Bae Hannam University</p>
WP-027	<p><b>Development of a Multi-Sensor-Based Defect Classification and Endpoint Prediction Model for Semiconductor Metal Etching Process Using Machine Learning</b></p> <p>Minseo Kim<sup>1</sup>, Suyeon Kim<sup>2</sup>, Heejin Moon<sup>3</sup>, and Dagyeong Hong<sup>4</sup></p> <p><sup>1</sup>Dong-Eui University, <sup>2</sup>Pusan National University, <sup>3</sup>Kyungpook National University, <sup>4</sup>Seoul National University of Science &amp; Technology</p>
WP-028	<p><b>Plasma-Enhanced Atomic Layer Etching for Fine Line Patterns of Next-Generation Interconnect Materials</b></p> <p>Daehan Won<sup>1,2</sup>, Harin Song<sup>1,2</sup>, Hongju Yang<sup>1,2</sup>, Hojin Chung<sup>1,2</sup>, Chee Won Chung<sup>1,2</sup>, and In-Hwan Baek<sup>1,2</sup></p> <p><sup>1</sup>Department of Chemical Engineering, Inha University, <sup>2</sup>Program in Semiconductor Convergence, Inha University</p>
WP-029	<p><b>Reaction Mechanism of Zirconium Oxide Atomic Layer Etching: An In vacuo XPS Study</b></p> <p>Mi-Soo Kim<sup>1</sup>, Eunju Ham<sup>1</sup>, Sejeong Jo<sup>1,2</sup>, Hyun-jeong Yoo<sup>1,2</sup>, Hye-Lee Kim<sup>1,2</sup>, Youn Seoung Lee<sup>3</sup>, Sun-Jae Kim<sup>1,2</sup>, and Won-Jun Lee<sup>1,2</sup></p> <p><sup>1</sup>Department of Nanotechnology and Advanced Materials Engineering, Sejong University, <sup>2</sup>Metal-organic Compounds Materials Research Center, Sejong</p>



	University, <sup>3</sup> Department of Information and Communication Engineering, Hanbat National University
WP-030	<p><b>Atomic Layer Etching of Cobalt Thin Films via Surface Fluorination and Low-Energy Ar+ Ion Activation</b></p> <p>Yeh Been Im<sup>1</sup>, Young Don Kim<sup>2</sup>, Hyeon Jun Cho<sup>3</sup>, Chin Wook Chung<sup>2,3</sup>, and Changhwan Choi<sup>1,2</sup></p> <p><sup>1</sup>Division of Materials Science and Engineering, Hanyang University, <sup>2</sup>Department of Semiconductor Engineering, Hanyang University, <sup>3</sup>Department of Electrical Engineering, Hanyang University</p>
WP-031	<p><b>H<sub>2</sub>O and O<sub>2</sub> Additive Effects on Cryogenic Etching of SiO<sub>2</sub> and Si<sub>3</sub>N<sub>4</sub> in CF<sub>4</sub>/Ar Plasmas under Self-Bias Conditions</b></p> <p>Kangwoo Lee<sup>1</sup>, Haegeon Jung<sup>2,3</sup>, Hakseung Lee<sup>2,3</sup>, Daeun Hong<sup>1</sup>, Minsung Jeon<sup>4</sup>, and Heeyeop Chae<sup>1,4</sup></p> <p><sup>1</sup>School of Chemical Engineering, Sungkyunkwan University, <sup>2</sup>Department of Semiconductor and Display Engineering, Sungkyunkwan University, <sup>3</sup>Samsung Institute of Technology, Samsung Electronics Co., Ltd., <sup>4</sup>Department of Semiconductor Convergence Engineering, Sungkyunkwan University</p>
WP-032	<p><b>Plasma Atomic Layer Etching of Molybdenum for Low-Damage and Precisely Controllable Etch Process</b></p> <p>Donguk Kim<sup>1</sup>, Hyunjin Yim<sup>2</sup>, Yehbeen Im<sup>2</sup>, Youngseo Na<sup>1</sup>, Kangbaek Seo<sup>1</sup>, Seungchae Lee<sup>2</sup>, Kanghyeok Lee<sup>1</sup>, Sangtae Park<sup>2</sup>, and Changhwan Choi<sup>1,2</sup></p> <p><sup>1</sup>Department of Semiconductor Engineering, Hanyang University, <sup>2</sup>Division of Materials Science and Engineering, Hanyang</p>
WP-033	<p><b>Atomic-Scale Smoothing of Cobalt Thin Films via a Plasma-Enhanced Quasi-ALD/ALE Supercycle</b></p> <p>SangTae Park<sup>1</sup>, HyunJin Lim<sup>1</sup>, YehBeen Im<sup>1</sup>, Young Seo Na<sup>2</sup>, SeungChae Lee<sup>1</sup>, KangBaek Seo<sup>2</sup>, DongUk Kim<sup>2</sup>, KangHyeok Lee<sup>2</sup>, and Changhwan Choi<sup>1,2</sup></p> <p><sup>1</sup>Division of Materials Science and Engineering, Hanyang University, <sup>2</sup>Department of Semiconductor Engineering, Hanyang University</p>
WP-034	<p><b>유기가스를 이용한 몰리브덴 박막의 플라즈마 강화 원자층 식각</b></p> <p>정호진<sup>1,2</sup>, 양홍주<sup>1,2</sup>, 원대한<sup>1,2</sup>, 송하린<sup>1,2</sup>, 정지원<sup>1,2</sup>, 백인환<sup>1,2</sup></p> <p><sup>1</sup>Department of Chemical Engineering, Inha University, <sup>2</sup>Program in</p>



WP-035	Semiconductor Convergence, Inha University
	<p><b>Silicon Oxide Etch Rate Model with Optical Emission Spectroscopy and VI- Probe</b></p> <p>Eunchong Park<sup>1</sup>, Minseong Kim<sup>2</sup>, Sanghee Han<sup>3</sup>, Jaehyeon Kim<sup>3</sup>, and Heeyeop Chae<sup>2,3</sup></p> <p><sup>1</sup>Department of Nano Science and Technology, SKKU Advanced Institute of Nanotechnology, Sungkyunkwan University, <sup>2</sup>Department of Semiconductor Convergence Engineering, Sungkyunkwan University, <sup>3</sup>School of Chemical Engineering, Sungkyunkwan University</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE3 (6층, 로비)

## [WP] 포스터세션

### V. Quantum Technology 분과

WP-371	<p><b>Design and Simulation of a 2-Qubit Superconducting Quantum Processor</b> Jiwon Seok, Seung-Young Seo, and Jae-Yoon Sim Department of Electronic and Electrical Engineering, POSTECH</p>
WP-372	<p><b>Anharmonic GHz Phonon Modes in Josephson Junction Tunnel Barriers: A First-Principles Study</b> Yosep Park<sup>1</sup> and Yeonghun Lee<sup>1,2</sup> <sup>1</sup>Department of Intelligent Semiconductor Engineering, Incheon National University, <sup>2</sup>Department of Electronics Engineering, Incheon National University</p>
WP-373	<p><b>Site-Controlled Quantum Dot Embedding in GaAs Nanowires on Silicon</b> Illia Tikhonov<sup>1,2</sup>, Sung-Yul L. Park<sup>1</sup>, Ga Hyun Cho<sup>1,3</sup>, and Jindong Song<sup>1,2</sup> <sup>1</sup>KIST, <sup>2</sup>University of Science and Technology, <sup>3</sup>Hanyang University</p>
WP-374	<p><b>Design and Optimization of 493 nm Inversely Tapered Edge Couplers for Low-Loss Coupling in Ba<sup>+</sup> Ion-Trap Quantum Computing Platforms</b> Seung-Gun Kim<sup>1</sup>, Jaewoo Kim<sup>1</sup>, Chiyoon Kim<sup>2</sup>, Changsoon Kim<sup>3</sup>, Taehyun Kim<sup>2</sup>, Donghwan Ahn<sup>1</sup>, and Youngmin Kim<sup>1</sup> <sup>1</sup>School of Materials Science and Engineering, Kookmin University, <sup>2</sup>Department of Computer Science and Engineering, Seoul National University, <sup>3</sup>Department of Intelligence and Information, Seoul National University</p>
WP-375	<p><b>Scalable Ground-State Cooling of 40Ca<sup>+</sup> Ion Chains via Electromagnetically Induced Transparency and Observation of Mode Mixing</b> Kim Keumhyun, Lee Hyegoo, SHIN Yongha, HAN Sangsoo, CHO Junhee, KIM Myunghun, GWON Sehyeon, Moon Youngil, and LEE Moonjoo Electrical Engineering, POSTECH</p>



WP-376	<p><b>Hybrid Quantum-Classical DMFT for Hubbard Model</b></p> <p>Juyeon Kim and Yeonghun Lee</p> <p>Department of Electronics Engineering, Incheon National University</p>
WP-377	<p><b>Quasiperiodic Dynamics of a Trapped-Ion Mechanical Oscillator</b></p> <p>Myunghun Kim, Sehyeon Gwon, Sangsoo Han, Junhee Cho, Keumhyun Kim, Hyegoo Lee, Yongha Shin, Youngil Moon, Kiyanoush Goudarzi, and Moonjoo Lee</p> <p>Department of Electrical Engineering, POSTECH</p>
WP-378	<p><b>양자점 단일광자 결합을 위한 MgO 도핑 TFLN 기반 광대역·편광 비의존 모드 사이즈 컨버터</b></p> <p>김보성, 김구환, 김홍석, 문기원, 주정진, 박재규</p> <p>한국전자통신연구원 양자기술연구본부 양자젠서연구실</p>
WP-379	<p><b>Experimental Implementation of Tunable Spin-Spin Couplings between 40Ca<sup>+</sup> Ions</b></p> <p>LEE Hyegoo, KIM Keumhyun, SHIN Yongha, HAN Sangsoo, CHO Junhee, MOON Young Il, KIM Myunghun, GWON Sehyeon, and LEE Moonjoo</p> <p>Electrical Engineering Department, POSTECH</p>
WP-380	<p><b>Anti-Reflection Coating for Integrated-Photonic-Circuit-Based Ba<sup>+</sup> Trapped-Ion Chips</b></p> <p>Uihwan Jeong<sup>1,2,3</sup>, Chiyoon Kim<sup>1,2,3</sup>, Suhan Kim<sup>1,2,3</sup>, Kwangyeul Choi<sup>1,2,3</sup>, Seungwoo Yu<sup>1,2,3</sup>, Changsoon Kim<sup>4</sup>, and Taehyun Kim<sup>1,2,3</sup></p> <p><sup>1</sup>Department of Computer Science and Engineering, Seoul National University, <sup>2</sup>Automation and System Research Institute, Seoul National University, <sup>3</sup>Inter-university Semiconductor Research Center, Seoul National University, <sup>4</sup>Department of Intelligence and Information, Seoul National University</p>



2026-01-28(수), 10:00-19:00

(공식발표시간: 17:30-19:00)

ZONE3 (6층, 로비)

## [WP] 포스터세션

### A. Interconnect & Package 분과

WP-381	포트 모델링 기법을 사용한 S-파라미터 시뮬레이션-측정 상관성 개선 표승수 <sup>1</sup> , 김문정 <sup>1</sup> , 진병규 <sup>2</sup> <sup>1</sup> 국립공주대학교 전기전자제어공학과, <sup>2</sup> 보스반도체
WP-382	소재 및 공정 기반 모델링을 사용한 S-파라미터 정합성 향상 이현아 <sup>1</sup> , 박혜준 <sup>2</sup> , 김문정 <sup>1</sup> <sup>1</sup> 국립공주대학교 전기전자제어공학과, <sup>2</sup> 아이원
WP-383	PCB 전송선로의 임피던스 불연속 구간에 대한 전기적 특성 분석 정준호 <sup>1</sup> , 진병규 <sup>2</sup> , 김문정 <sup>1</sup> <sup>1</sup> 국립공주대학교 전기전자제어공학과, <sup>2</sup> 보스반도체